
MHz X-ray imaging with Silicon Pixel Detectors



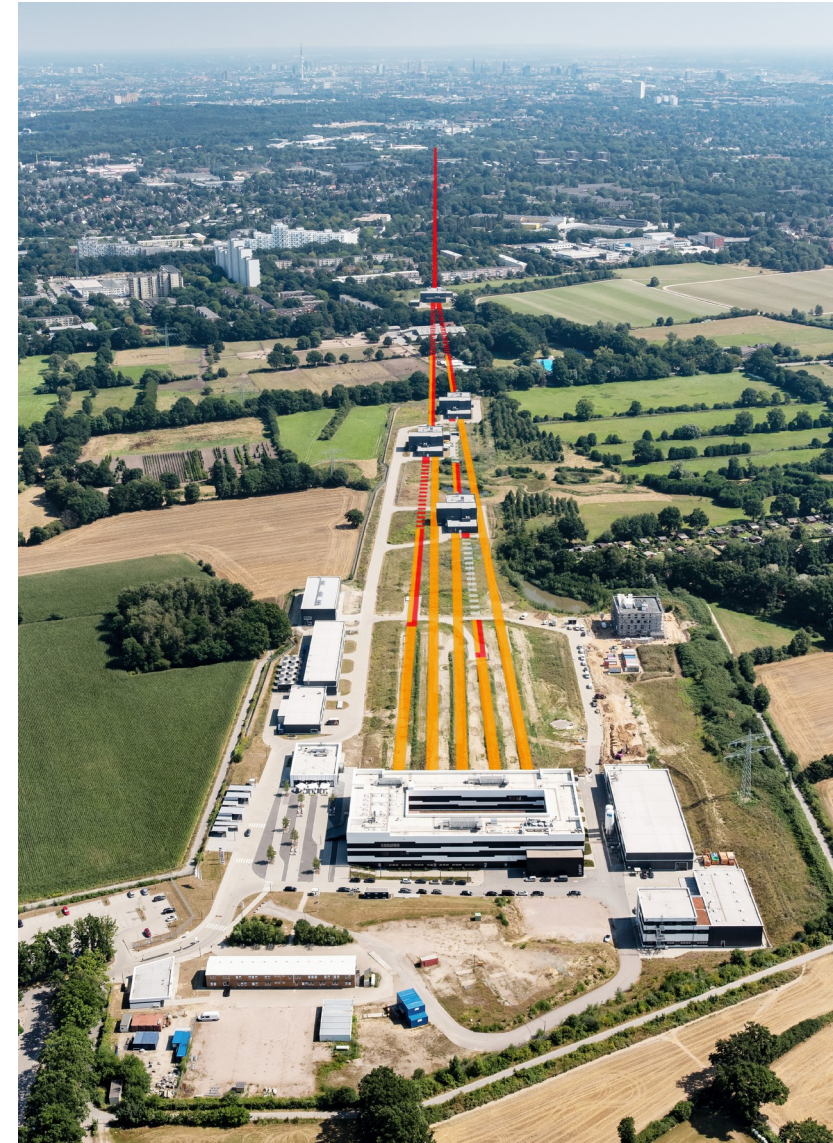
Marco Ramilli

on behalf of the Detector Group of European XFEL

8th EIROforum School on Instrumentation
ESO Headquarters, Garching, 17.05.2024

Outline

- Introduction
 - The European XFEL beam
 - Experiments at EuXFEL
- Detector Requirements
- How to deal with high dynamic range
 - Dynamic gain switching (AGIPD)
 - Non-linear response (DEPFET DSSC)
- MHz burst mode operation
 - Analog storage cells (AGIPD)
 - On-chip analog-to-digital conversion (DSSC)
- Raw data correction at European XFEL
- Conclusions



Acknowledgment

- AGIPD Consortium (H. Graafsma)
 - DESY, PSI, Uni Bonn, Uni Hamburg



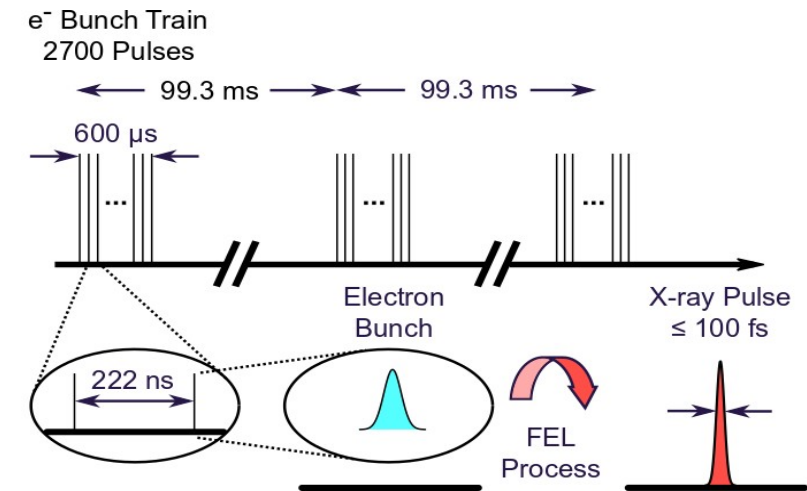
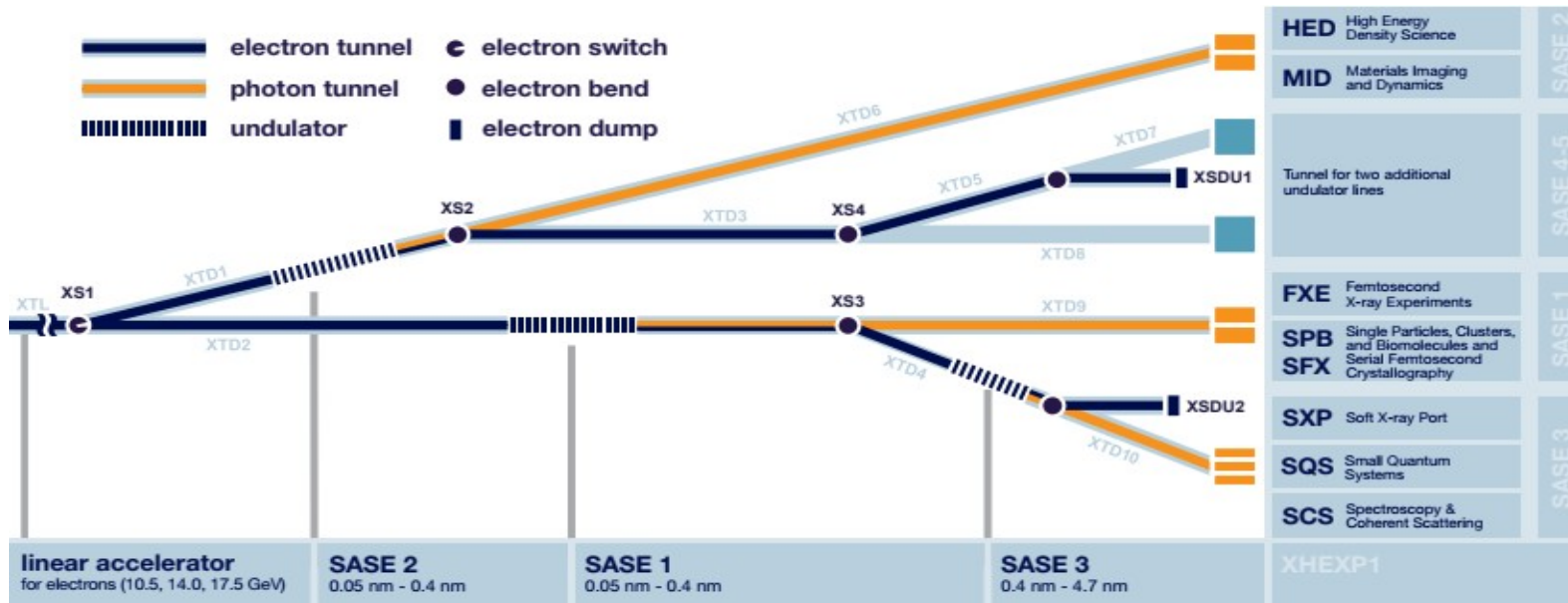
- DSSC collaboration (M. Porro)
 - EuXFEL, DESY, PoliMi, Uni BG, Uni Heidelberg, pnSensor, MPG-HLL, INFN



- European XFEL
 - Data Department (S. Aplin)
 - ▶ **DET Group**, CTRL, ITDM, EEE, DA
 - SPB/SFX instrument (A. Mancuso/R. Bean)
 - MID instrument (A. Madsen)
 - FXE (Ch. Milne)
 - HED (U. Zastra)
 - SCS (A. Scherz)
 - SQS (M. Meyer)



Introduction: European XFEL



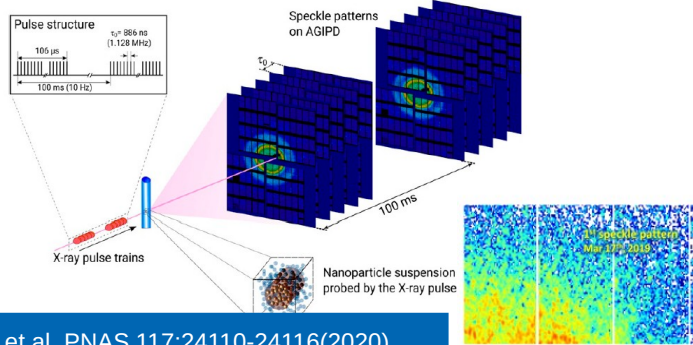
- Three main undulator systems (SASE 1, 2, 3)
 - Supply seven scientific instruments
 - SPB/SFX, FXE, MID, HED ('hard X-ray')
 - 6 keV < E < 25 keV
 - SCS, SQS, SXP ('soft X-ray')
 - 0.25 keV < E < 3 keV

- 10 Hz train rate
- Bunch train internal structure
 - 2700 pulses for 600 μs
 - 4.5 MHz pulse rate (~222 ns spaced)
 - Lasing pulses < 100 fs width
- Pulses of ~10¹⁴ photons
 - Most experiments are pulse-resolved
 - Detectors need to cope with bunch train structure

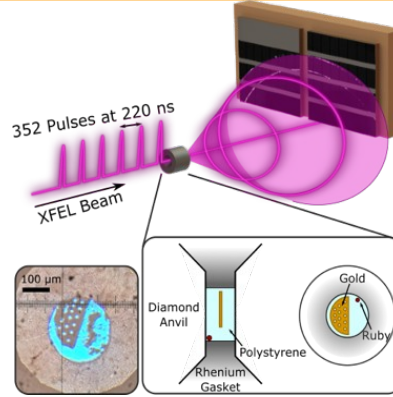
Introduction: experiments

Study of materials in extreme conditions

MHz XPCS to look at system dynamics

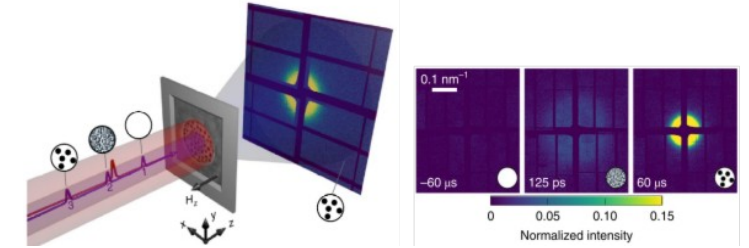


Lehmkuhler et al. PNAS 117:24110-24116(2020)



M. Frost et al., accepted by Nature Astronomy (2023)

X-ray scattering experiments

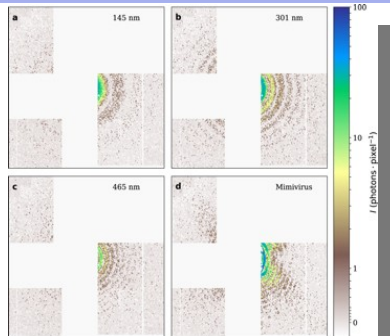


F. Büttner et al., Nat. Mater., 20, 30-37 (2021)

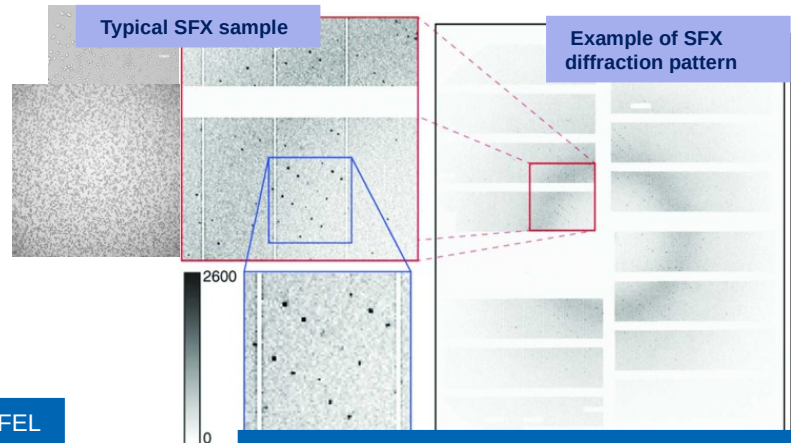
Serial femtosecond protein crystallography (SFX)

Single-particle imaging

Examples of scattering patterns from IrCl₃ and Mimivirus.



Sobolev, E. et al. Megahertz single-particle imaging at the European XFEL Commun Phys 3, 97 (2020)



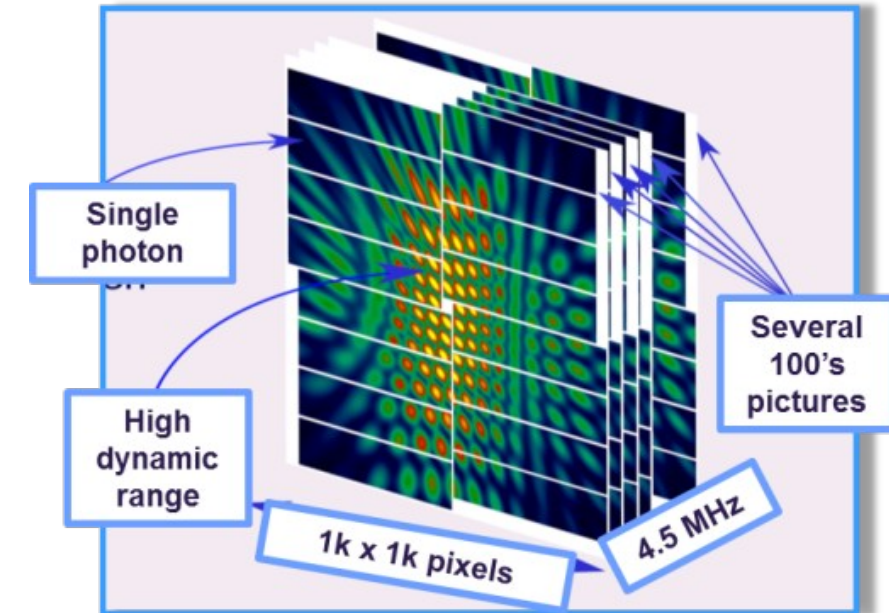
Wiedorn, M.O., et al. Megahertz serial crystallography. Nat Commun 9, 4025 (2018)

Oversimplifying:


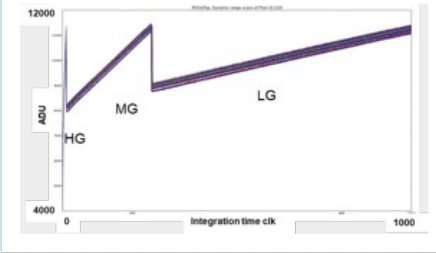
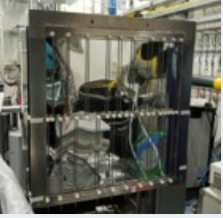
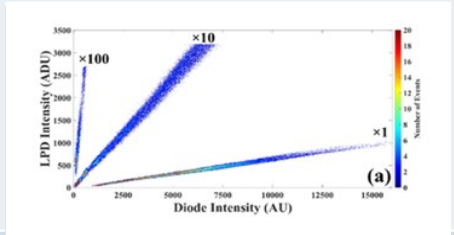

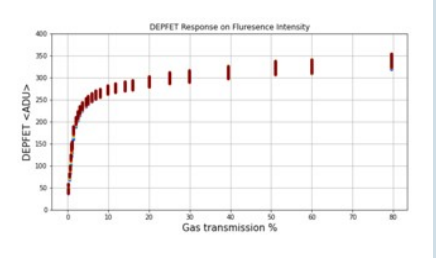
- X-rays from pulse interact with sample (sample often destroyed)
- Interaction creates a 2D X-ray 'pattern' (Contains physical information)
- Detectors need to image this pattern

Detector requirements

- **The detector needs to cover as much solid angle as possible**
 - Reduced pixel pitch for spatial resolution
 - ▶ ~1 Mpix with ~200 μm pixel pitch
- **The detector needs to cope with 4.5 MHz burst pulse rate**
 - High detector occupancy
 - ▶ No event-driven readout
 - No time to read out the whole image in between pulses
 - ▶ Images have to be stored and then readout in between trains
- **Huge difference in signal in the same image**
 - The detector needs a wide dynamic range
 - The same pixel needs to accurately detect:
 - ▶ Single photons
 - ▶ Tens of thousands of photons ($\sim 10^4$ ph/pixel)
- **European XFEL environment is harsh for the detector**
 - High doses are delivered (sometimes instantaneously)
 - ▶ Detector should be radiation tolerant as much as possible
 - ▶ Calibration constant need to be updated frequently



MHz Imaging detectors for EuXFEL

Detector	Specs	Gain Mechanism	Gain	Start of Operation
AGIPD 	352 memory cells (analog) 200 μ m x 200 μ m sq. pixels 1-10 ⁴ 12 keV ph 3-20 keV Modular: 16 (1MPix) or 8 (0.5MPix) modules	3 gains with automatic switching		AGIPD1M (SPB/SFX): 2017 AGIPD1M (MID): 2019 AGIPD500K: 2020 (new gen.) AGIPD4M (SPB/SFX): 2024 (new gen.) AGIPD1M (HED): 2024 (new gen)
LPD 	(3x)512 memory cells (analog) 500 μ m x 500 μ m sq. pixels 1-10 ⁵ 12 keV ph 7- 20 keV Modular: 16 module (1MPix)	3 parallel gain stages with on front-end selection		LPD (FXE): 2017
DSSC 	800 memory cells (digital) 204 μ m x 236 μ m hex. pixels N x 256 ph @ 4.5 Mhz N x 512 @ f \leq 2.2 MHz N \leq 1 for single ph sensitivity 0.5 – 6 keV Modular: 16 modules (1MPix)	Linear response (miniSDD), non-linear signal compression in sensor (DEPFET)		DSSC1M (SCS): 2019 DSSC DEPFET: 2024

Hybrid pixel detector technology

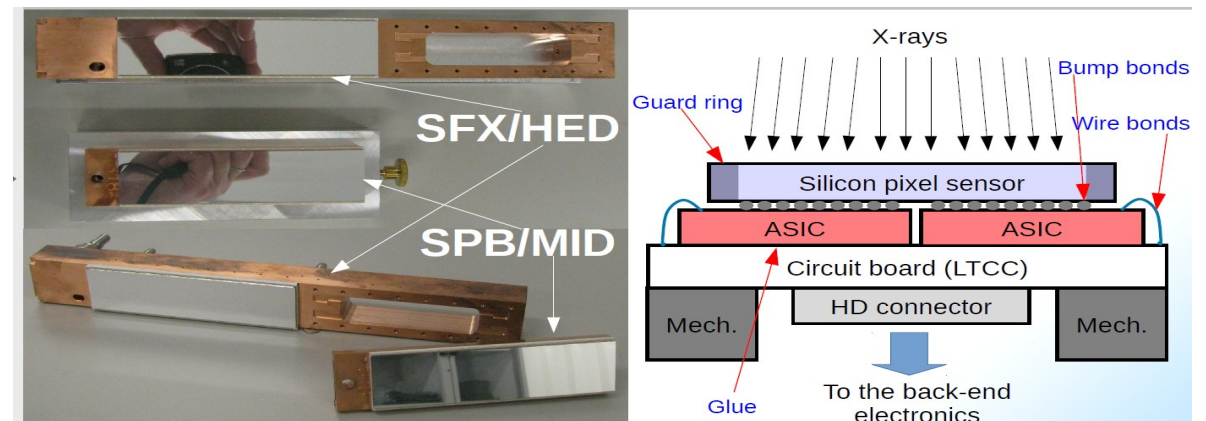
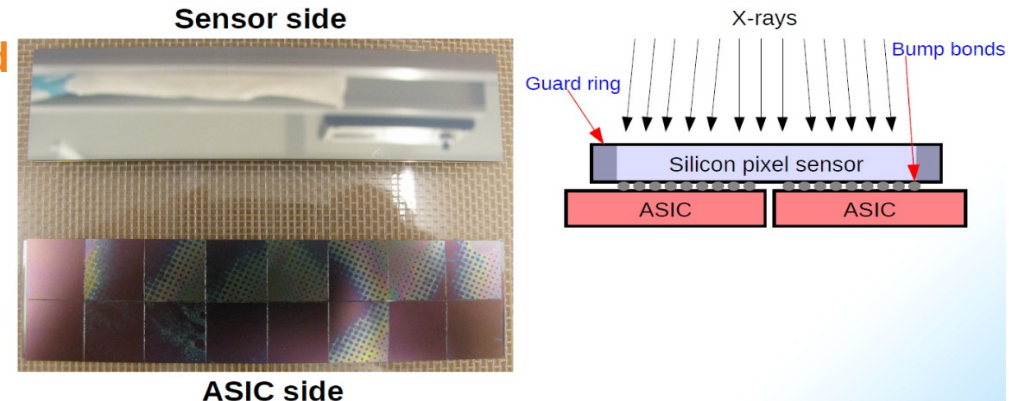
■ Detection component and front end readout are developed separately

- Pixellated sensor
 - ▶ Typically silicon in proportional mode
 - ▶ Other solutions possible e.g.:
 - ▶ CdZnTe, GaAs for higher photon energy detection
 - ▶ LGADs to improve S/N ratio at soft X-ray energies
 - ▶ **DEPFET** ...
- Signal generated in sensor is read out by ASIC
 - ▶ ASIC is also pixellated
- Sensor and ASIC are connected on a pixel-by-pixel basis
 - Bump-bonding between contacts
 - ASIC output wire-bonded to rest of read out chain

Example of single AGIPD module:

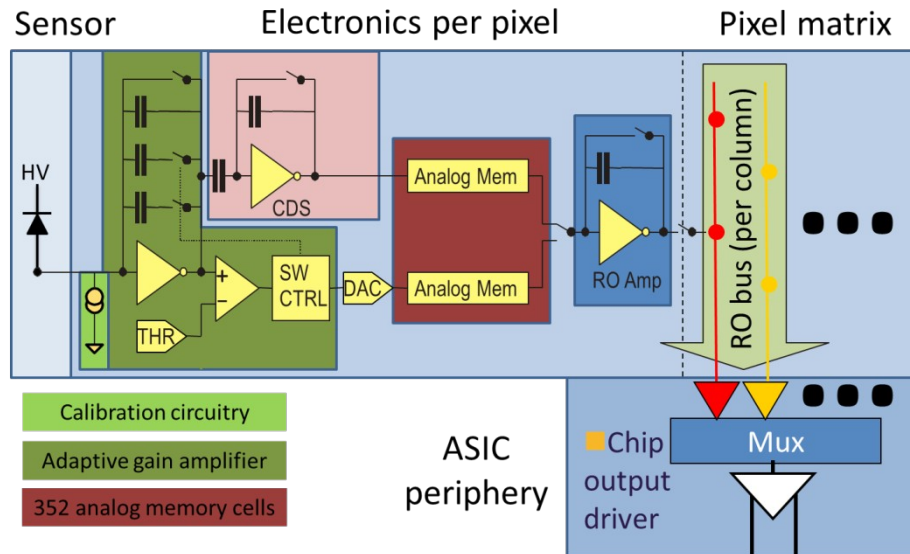
Sensor 128 x 512 pixels

2 x 8 read-out chips connected to sensor via bump-bonding

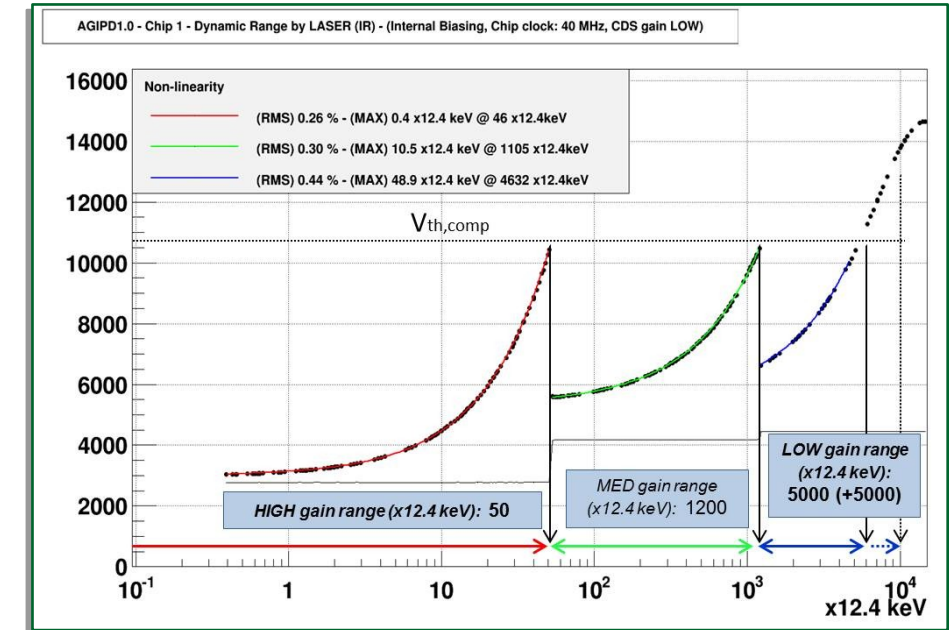


High dynamic range requirement

High dynamic range adaptive gain: the AGIPD detector

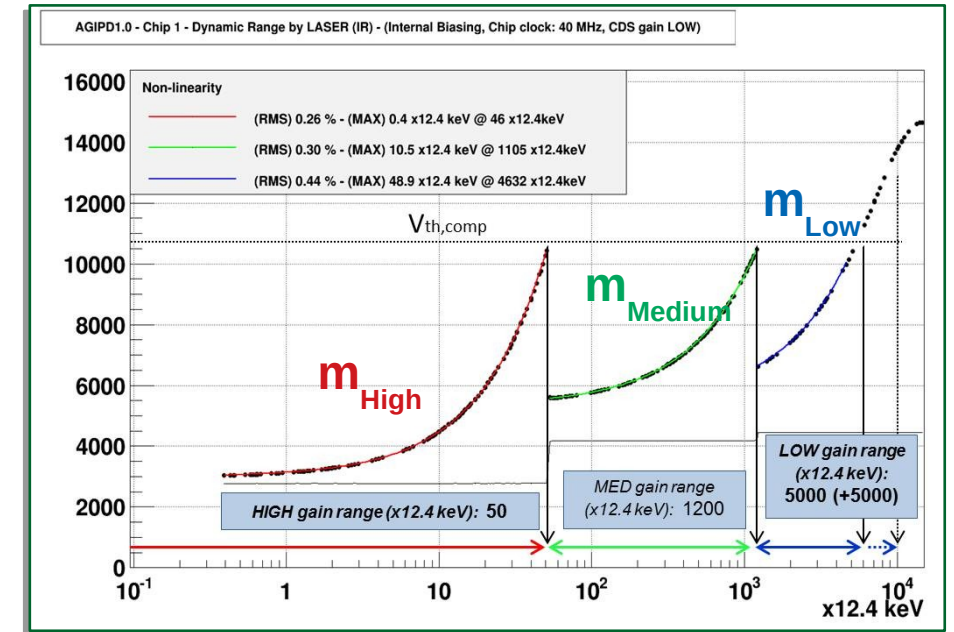
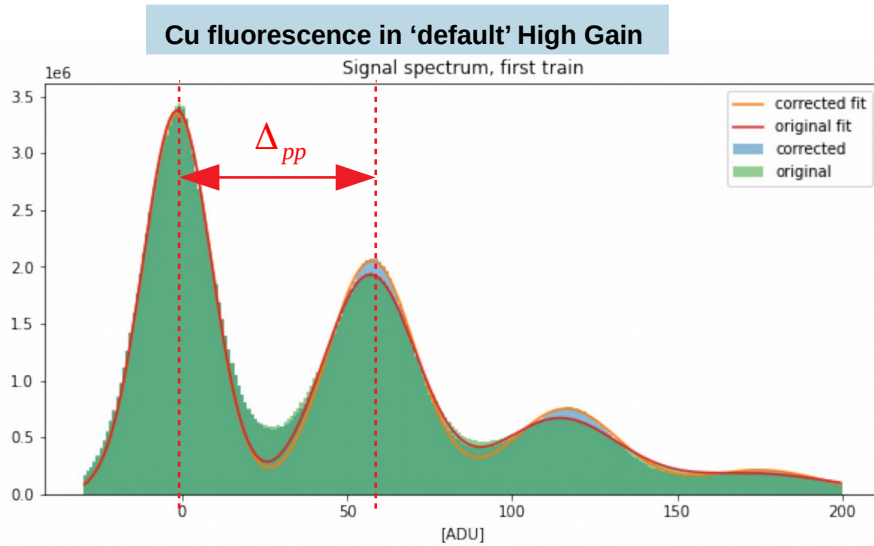


$$V_{out} = \frac{-Q_i}{C_f}$$



- Charge-integrating pre-amplifier (pre-amp)
- Pre-amplifier with **dynamic gain switching (DGS)**
 - Three feedback capacitors C_f
 - ▶ Three gains (High, Medium, Low)
 - Threshold comparator at the output node of pre-amp
 - ▶ If signal above V_{thr} additional capacitor is switched in
- Correlated Double Sampling (CDS)
- Readout output stored in analog storage cell
- 'gain stage' also stored analogically
- To correct raw data
 - Pedestal value to subtract
 - Conversion factor into physical unit (*gain factor*)
 - Information about the the 'gain stage'
 - ▶ **Six constants per pixel and per storage cell**

Dynamic gain switching calibration



Fluorescence spectra for High Gain calibration

- “absolute” calibration: conversion factor from ADC units → keV

Dynamic range scans for lower gains calibration (Medium and Low)

- Raw output as function of input signal

- Linear fit of the response

- “relative” calibration: fit slope m → slope ratio → gain factors ratio

Pedestal estimated with ‘dark’ runs

- Pre-amp forced switch for Medium and Low gain

$$G_{High} = \frac{\Delta_{pp}}{E_{ph}}$$

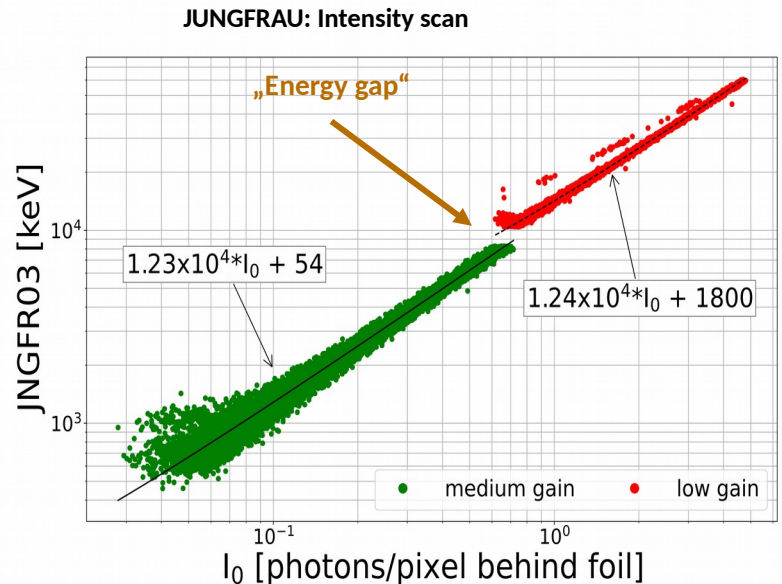
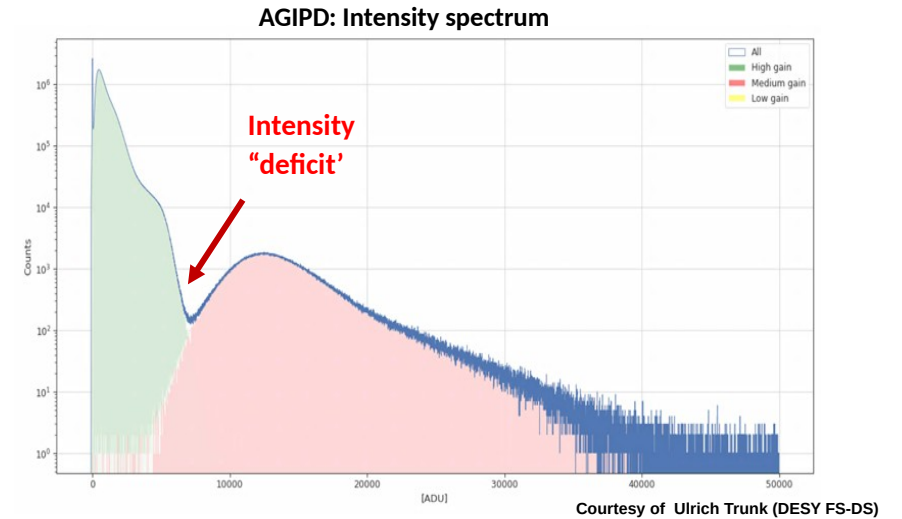
$$R_{HM} = \frac{m_{High}}{m_{Medium}}; R_{ML} = \frac{m_{Medium}}{m_{Low}}$$

$$G_{Medium} = \frac{G_{High}}{R_{HM}}$$

$$G_{Low} = \frac{G_{High}}{R_{HM} \times R_{ML}}$$

Dynamic gain switching data quality

- The AGIPD detector is in operation since 2017
 - Plenty of User Operation hours
 - ▶ **‘stress test’ of the goodness of calibration**
- The dynamic gain switching has been proved working
 - A few issues have been identified
- Gain switching region may show issues
 - **Intensities not mapped**
 - ▶ Reliability of the pedestal determination
 - ▶ Forced gain switch not always predictive
- Issues manifest in other detectors with dynamic gain switching architecture

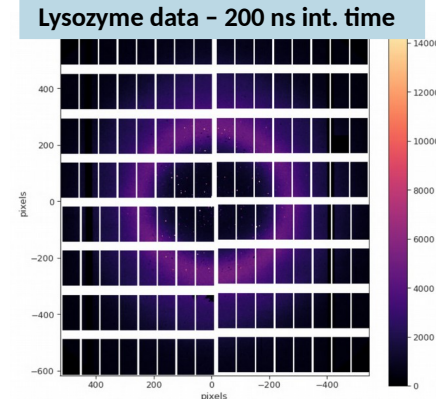
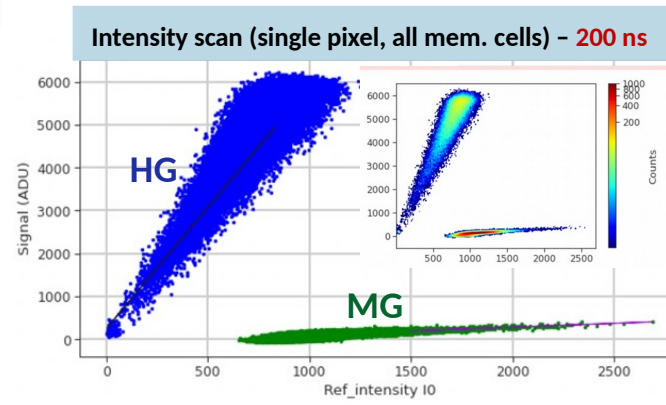
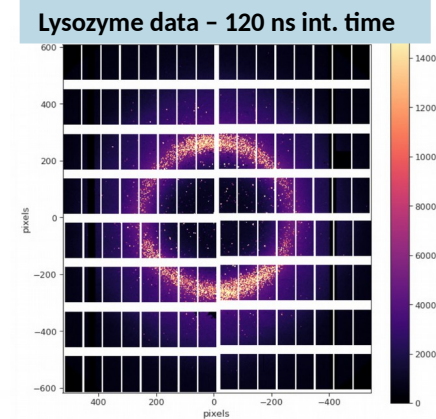
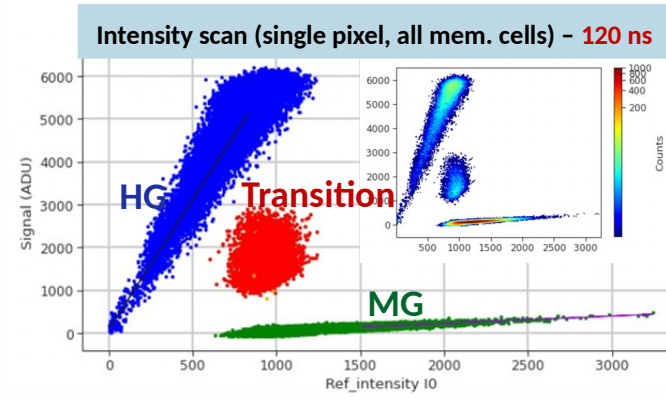
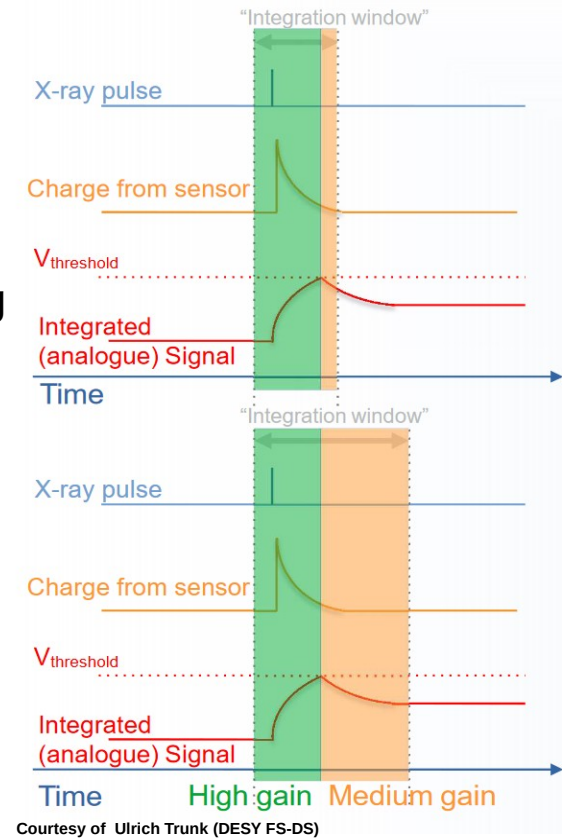


Sikorski, M.; Ramilli, M. . et al. “ First operation of the JUNGFRAU detector in 16-memory cell mode at European XFEL” Front. Phys., Volume 11 – 2024
<https://doi.org/10.3389/fphy.2023.1303247>

Dynamic gain switching data quality (cont'd)

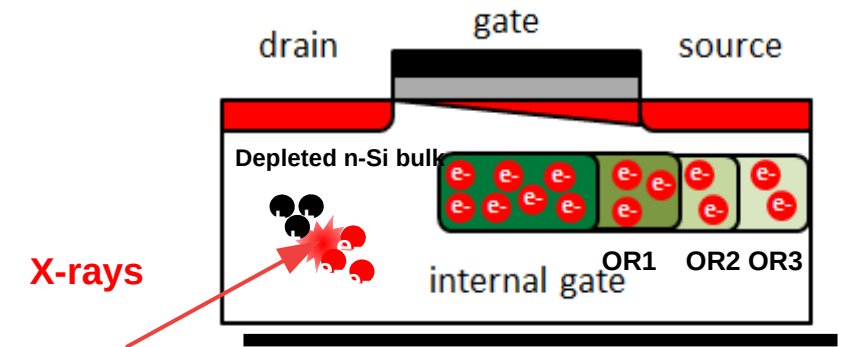
Late gain switching

- Signal sampled while still settling
 - ▶ Artifact in corrected image
- Encountered in other DGS detectors
- Possible solutions
 - Increase exposure time
 - ▶ AGIPD, JUNGFRAU
 - Inhibit late gain switching
 - ▶ GOTTHARD-II

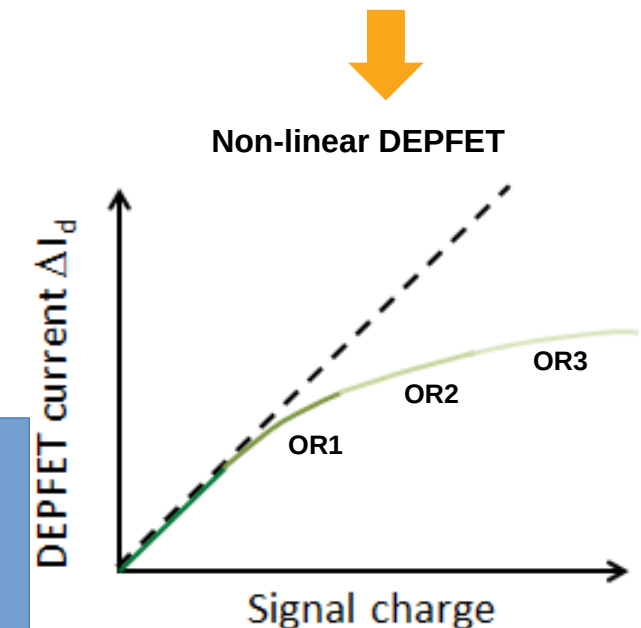


High dynamic range with non-linear response: the DSSC detector

- DSSC ASIC is bump bonded to **DEPFET sensors**
 - Depleted P-channel Field Effect Transistor
 - ▶ Invented by J. Kemmer and G. Lutz in late 1980s at MPI Munich
- FET integrated on a fully depleted n-Si bulk
 - In-pixel signal amplification
 - Potential minimum for electrons between source and drain
 - ▶ Charge accumulation induces charge in gate
 - ▶ Change of current between source and drain proportional to charge
- The DSSC DEPFET potential valley extends towards the source
 - Extracted charge will eventually fill the Overflow Regions (OR)
 - ▶ Gating effect of charge in OR less pronounced
- **The sensor response is not completely linear with extracted charge**
 - For small amounts it maintains a linear response
 - For increasing amounts it will eventually deviate from linearity



DEPFET: FET integrated on a fully depleted Si bulk

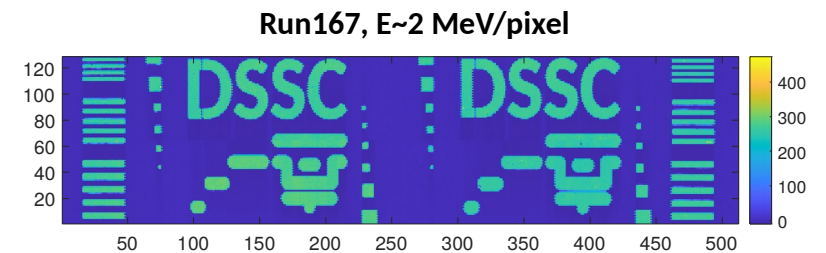
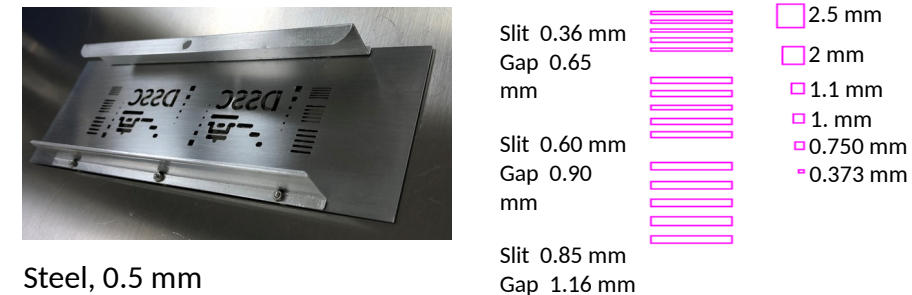
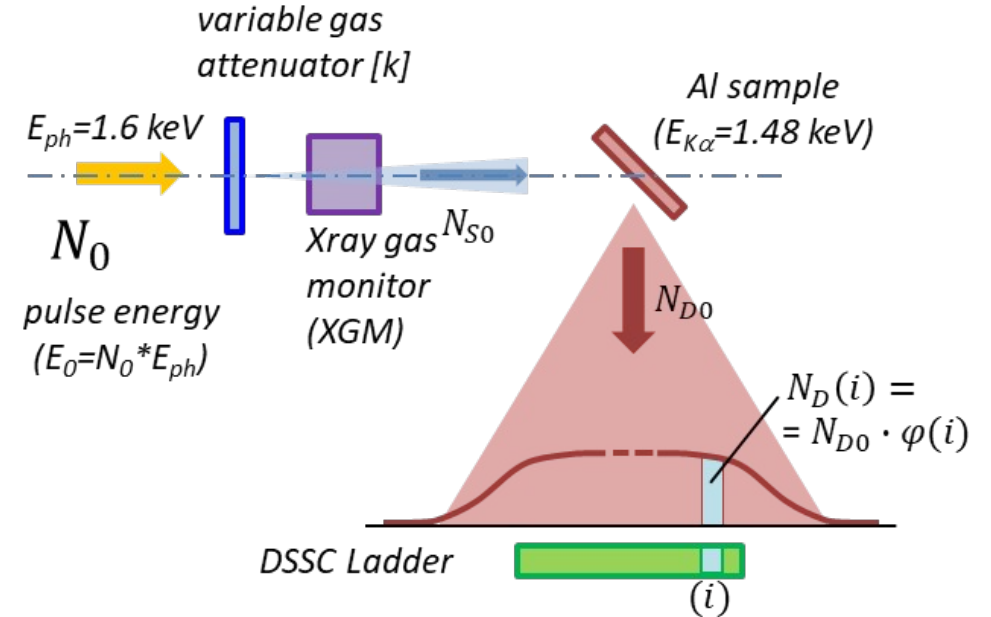


Lechner, P. et al. "DEPFET active pixel sensor with non-linear amplification" (2012) art. no. 6154112, pp. 563-568
doi:10.1109/NSSMIC.2011.6154112

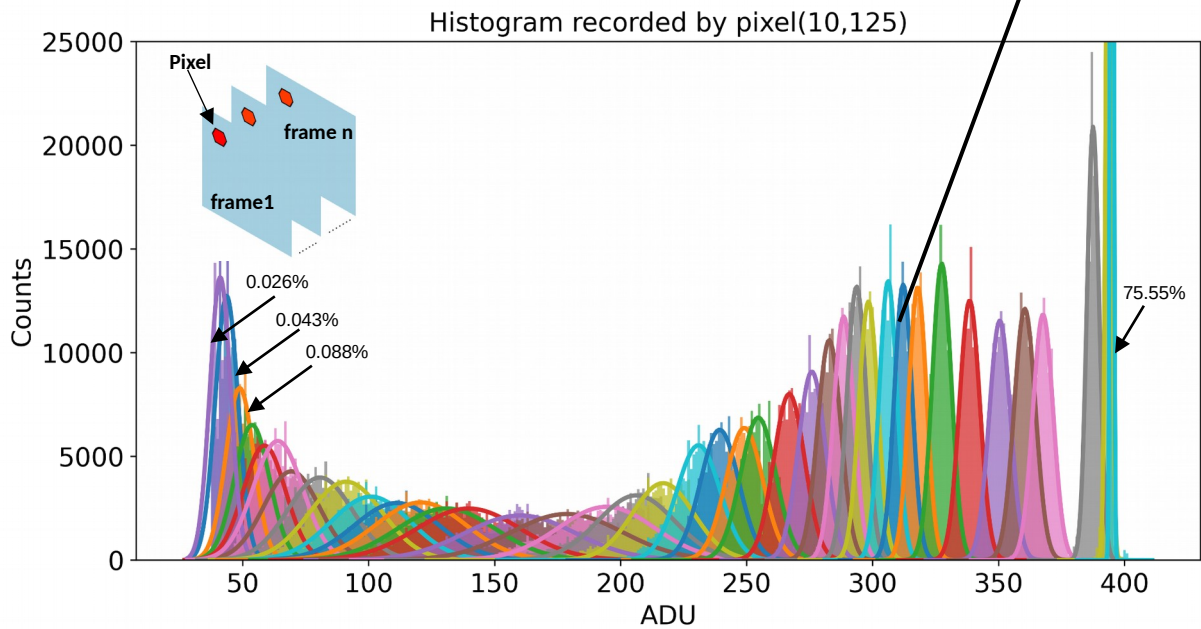
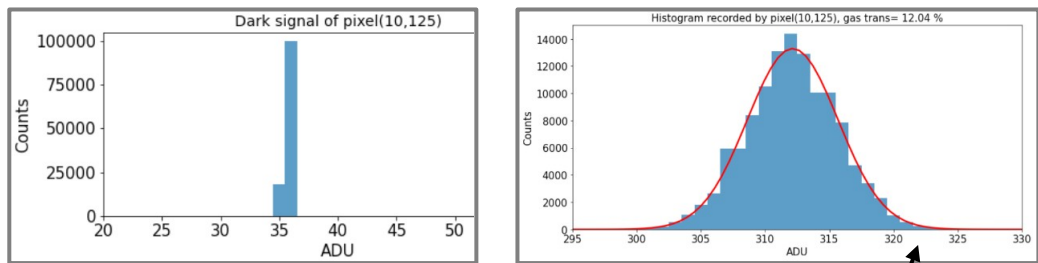
Aschauer, S.; et al. "First Results on DEPFET Active Pixel Sensors Fabricated in a CMOS Foundry - a Promising Approach for New Detector Development and Scientific Instrumentation". *J. Inst.* 2017, 12, P11013-P11013
doi:10.1088/1748-0221/12/11/p11013

DEPFET response calibration

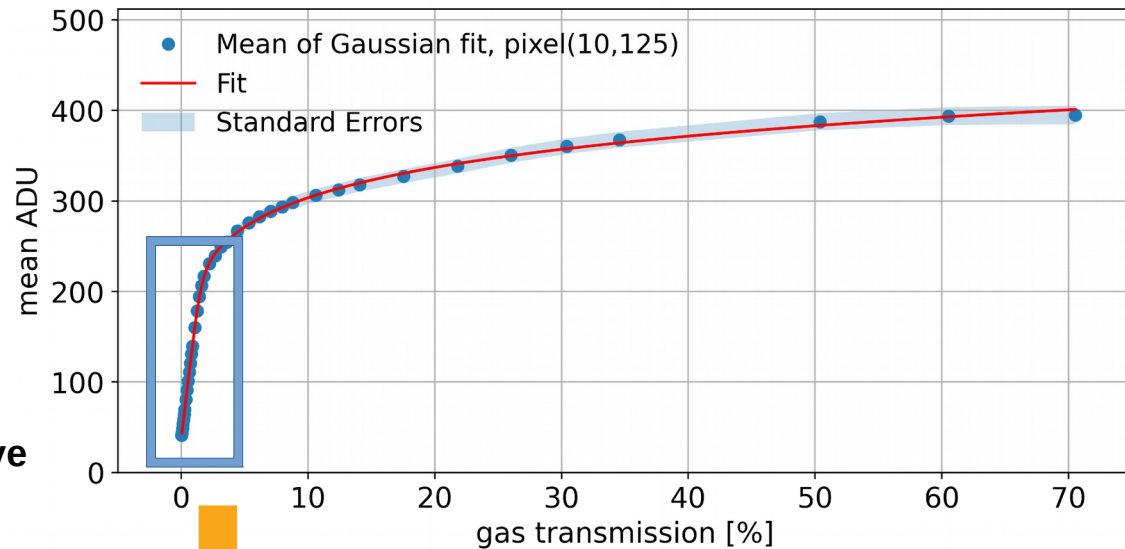
- Accurate calibration of the sensor response is needed
- Intensity scan of the whole dynamic range
- Performed in Nov. 2022 with Al fluorescence setup
 - EuXFEL beam used to generate K_{α} emission from Al target
 - ▶ Intensity on Al target provided by Gas Monitor (GM)
 - ▶ DSSC module illuminated by Al fluorescence
- Calibration idea:
 - Acquire the whole non-linear response (NLR) curve
 - ▶ Detector output as function of the GM output
 - Linear part → absolute calibration
 - ▶ Used to intercalibrate with GM
 - Absolute calibration of detector response to flux
 - Do it for every pixel



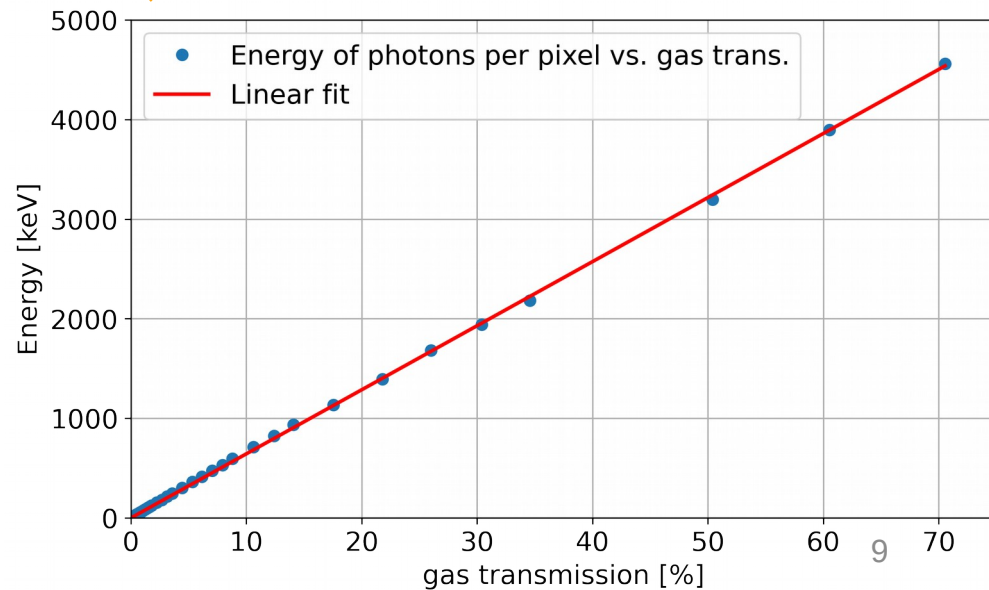
DEPFET response calibration



Non-linear response curve on pixel(10, 125)

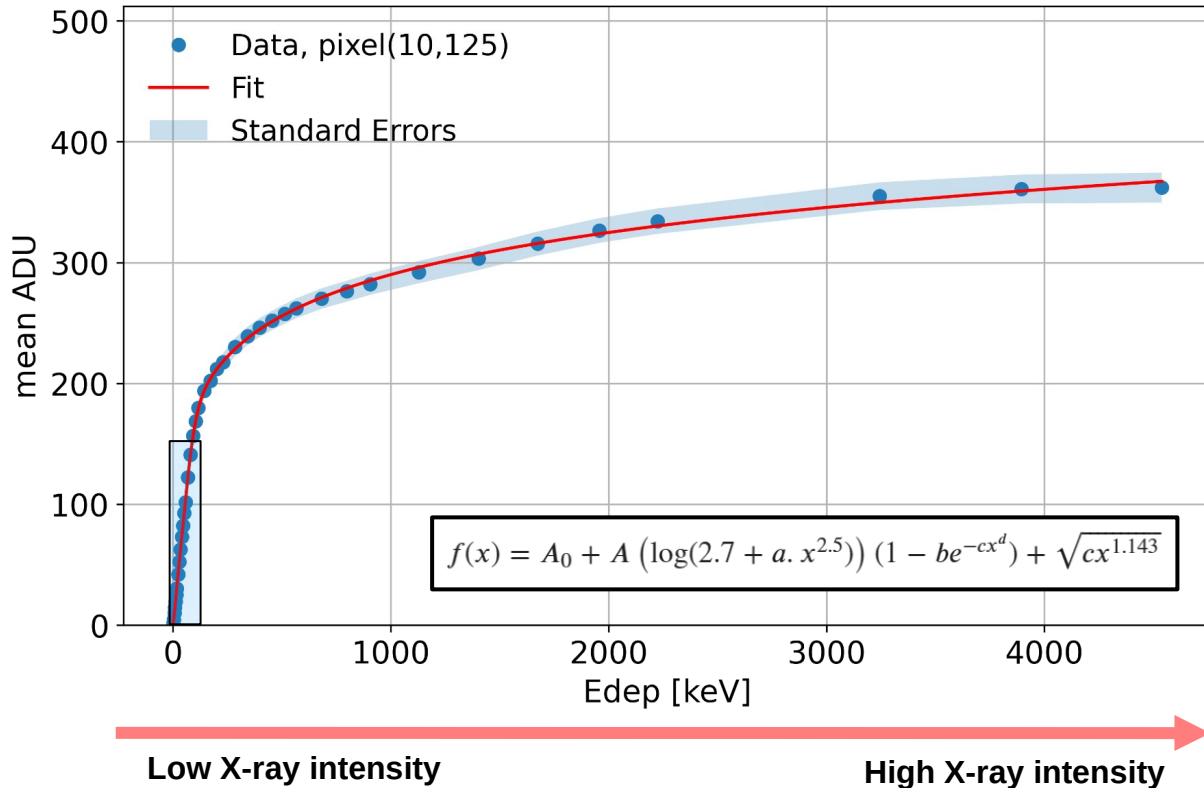


NLR curve



DEPFET response calibration

Non-linear response of a DEPFET pixels(10, 125)



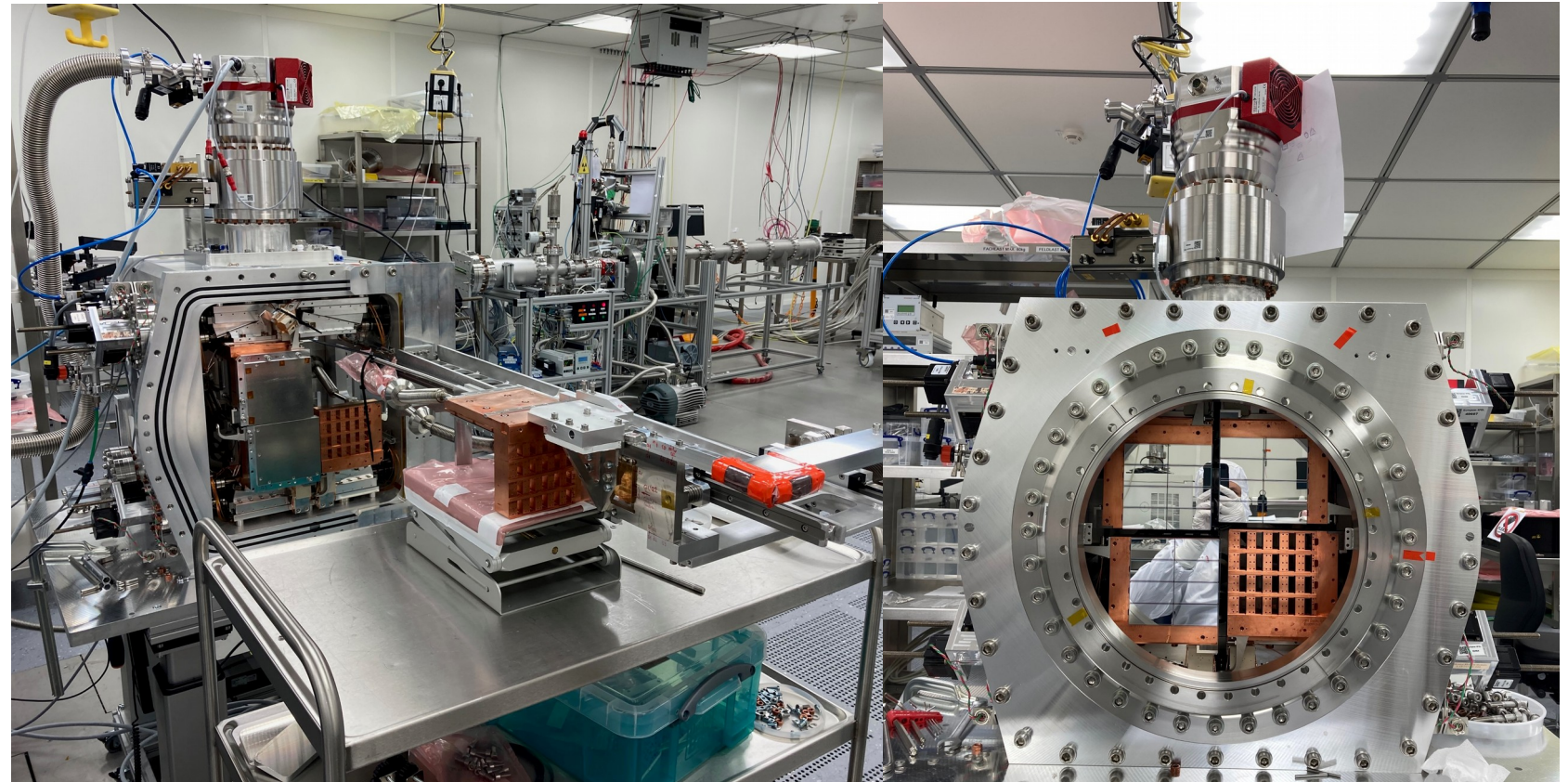
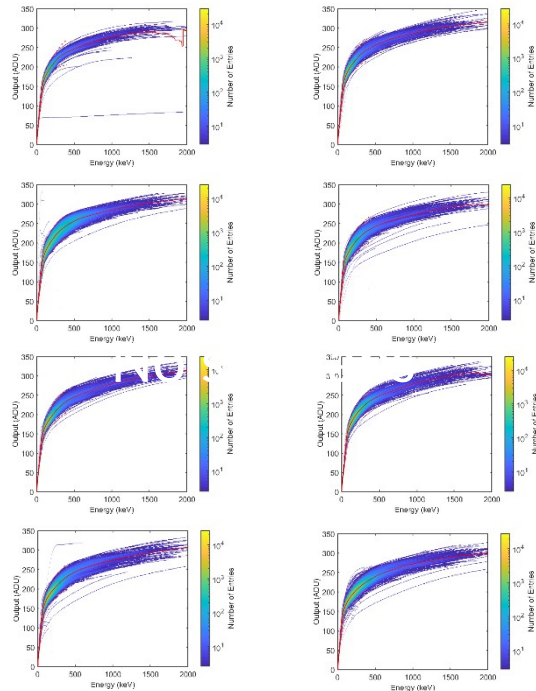
- Fit with phenomenological function
 - From fit a look up table is generated
 - ▶ Connects ADC value to Energy
- This is repeated for every pixel

```
# parm[0]=A0, parm[1]=Amp, parm[2]=a, parm[3]=b, parm[4]=c, parm[5]=d, R_Square
139.59288,17.66534,3.14228,8.95974,1.47839,1.36720,0.99907
149.63412,16.24460,2.96456,10.24886,1.46595,1.36926,0.99835
153.23758,15.58930,2.86062,10.90080,1.49613,1.37310,0.99810
145.84819,16.64584,3.49679,9.77680,1.66485,1.38416,0.99863
152.02387,16.08610,2.82930,10.41920,1.55998,1.40136,0.99819
149.56305,15.97035,3.10646,10.37618,1.59072,1.37933,0.99836
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143.51220,15.61933,2.56789,10.16151,1.56978,1.40634,0.99854
```

Maffessanti, S., Hansen, K. et al., "A 64k pixel CMOS-DEPFET module for the soft X-rays DSSC imager operating at MHz-frame rates". Nature Sci Rep 13, 11799 (2023) <https://doi.org/10.1038/s41598-023-38508-9>

A. Castoldi et al. "Qualification of the X-ray spectral performance of the DEPFET pixels of the DSSC imager", NIM A, 2023

DEPFET DSSC 1 Mpix camera assembly

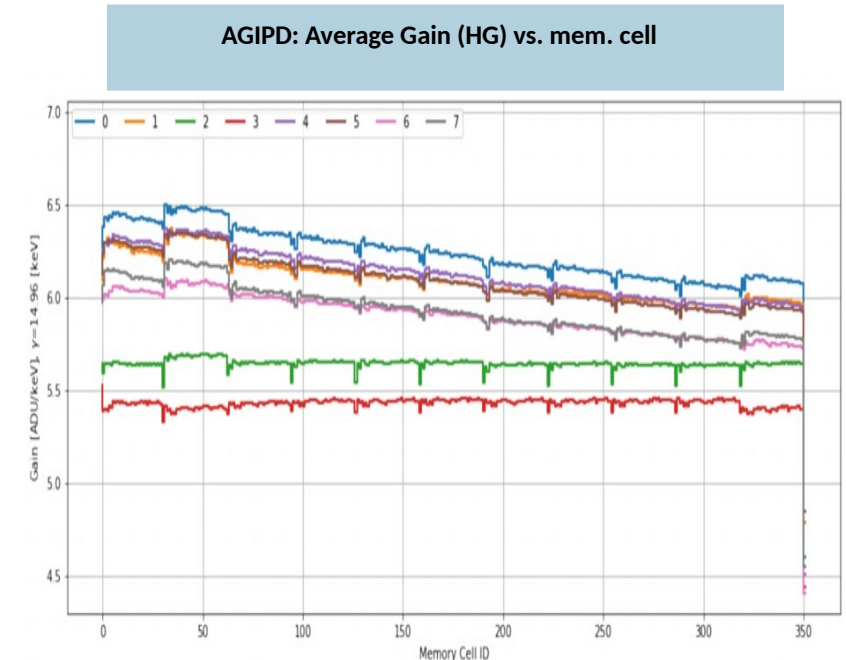
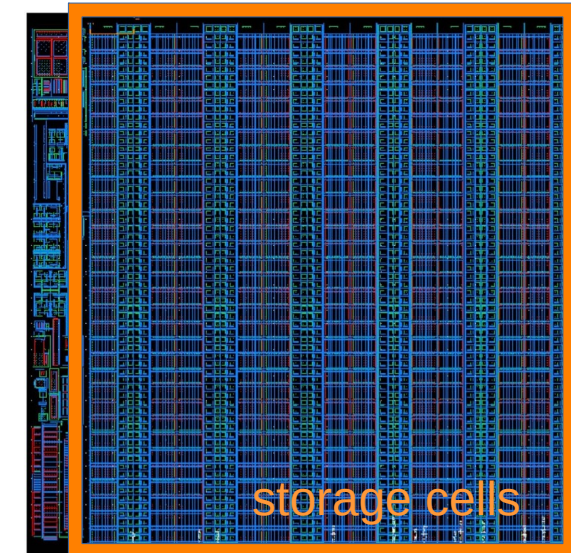


- DSSC equipped with DEPFET is being assembled at European XFEL
 - 3 out of 4 quadrants are in place
 - ▶ More DEPFET are being produced
 - **First users in 2025**
- ■ ■ European XFEL

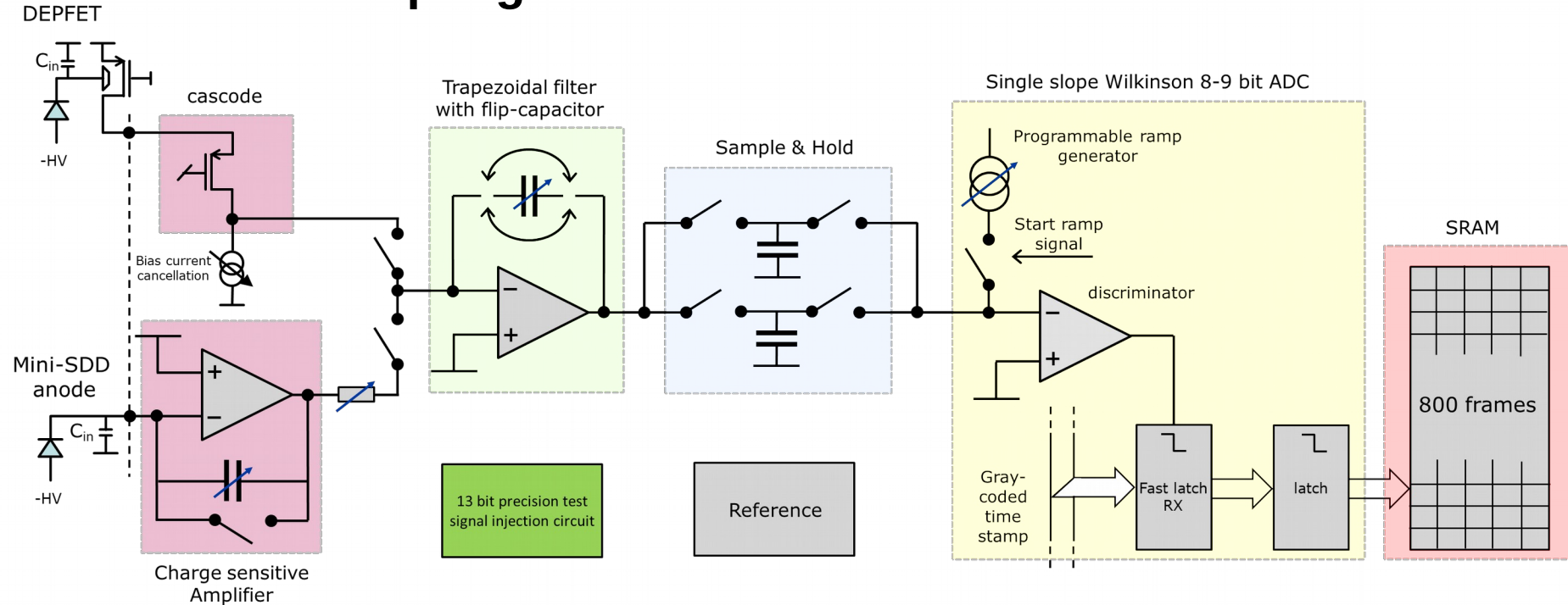
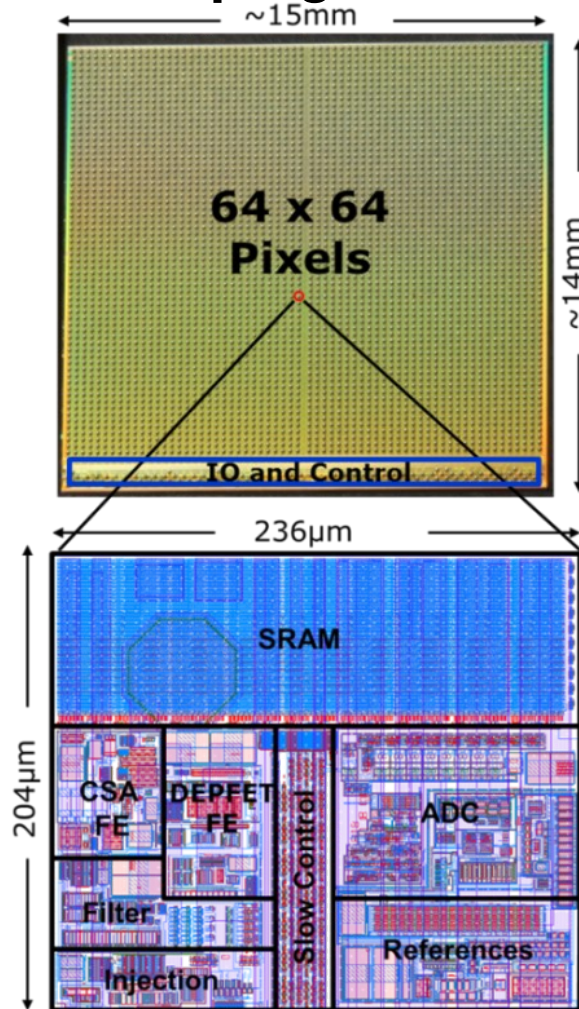
MHz burst frame rate requirement

Coping with MHz frame rate: analog storage

- Detector cannot be read out in less than 200 ns
- Images have to be stored somewhere and read out in between trains
- AGIPD chose the **analog storage cell solution**
 - **Each pixel is endowed with 352 capacitors**
 - Each capacitor holds the output of one acquisition
 - Capacitor values is read out and passed on the (off chip) ADC in between trains
- This simple solution has some drawback
 - The footprint for all these storage cells is ~80% of the pixel area
 - The storage cells are appreciably different from each other
 - ▶ **All the constants have to be produced for each storage cells**
 - ▶ To calibrate one pixel $6 \times 352 = 2112$ constants are needed!
 - Other effects:
 - ▶ Cross talk
 - ▶ Charge leak
- This simple solution requires substantial calibration effort to mitigate its effects



Coping with MHz frame rate: on-chip digitization

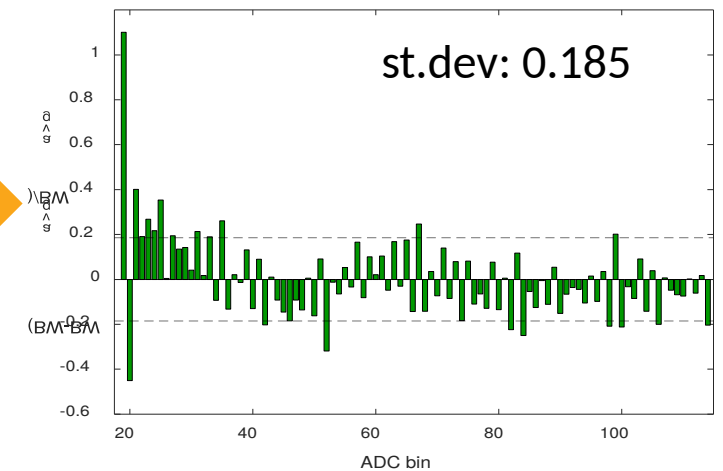
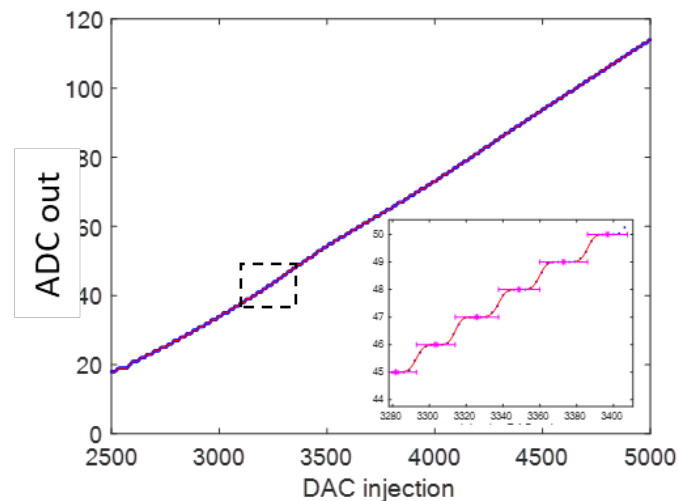
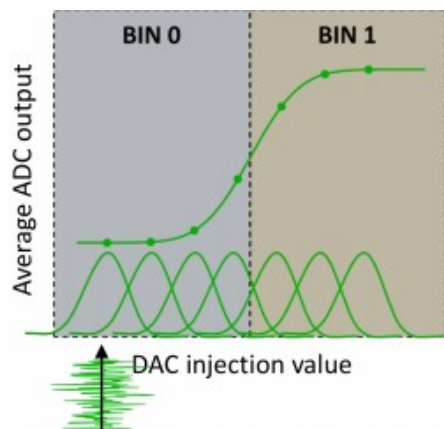


- DSSC opts for **on-chip digitization of the signal**
 - Signal passes amplification and filtering
 - Sample and hold stage
 - ▶ One capacitor stores the signal
 - ▶ The other has it read out and digitized by an analog-to-digital converter
 - ADC output stored in an SRAM with 800 images depth

Coping with MHz frame rate: ADC calibration

- The on chip ADC has 8 at 4.5 MHz
 - 9 bit at frame rates ≤ 2.2 MHz
 - ▶ Limited resolution (AGIPD off-chip ADC has 14 bits)
- **Differential non-linearity (DNL)**
 - One of the main qualifiers for ADC performances
 - **Deviation w.r.t. the ideal step of one LSB**
 - ▶ Measure of the “actual bin width” of the ADC
- Can be measured by injecting voltage in ADC in a controlled way
 - In this way the output is characterized
- DSSC DNL has been characterized with a 13 bit input DAC

$$DNL(i) = \frac{W(i) - W_{ideal}}{W_{ideal}}$$

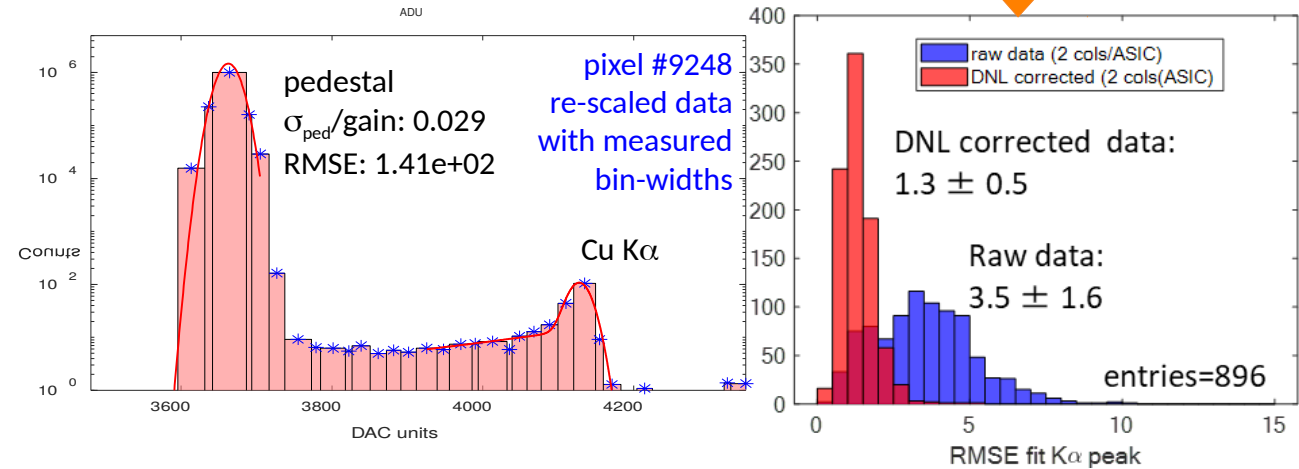
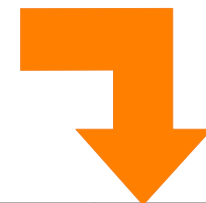
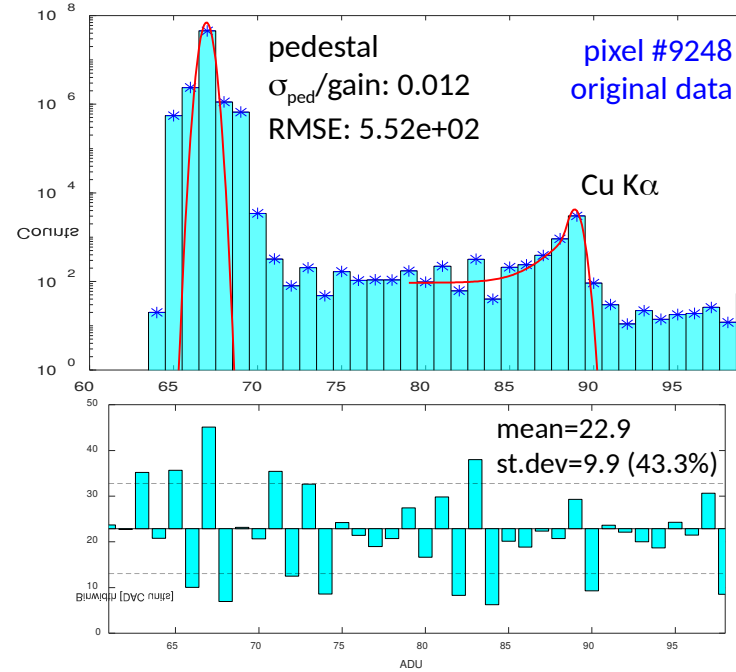


Coping with MHz frame rate: DNL correction

- Fluorescence measurements on DSSC
 - Some bins are over/under sampled
- DNL correction may be relevant
 - Spectroscopic measurements
 - weight the occurrences N in the i -th bin
 - ▶ Marked improvement of the peak resolution
 - ▶ Drop of the error on gain value estimate
- **Characterization of the DNL can be necessary**
- This information is then used in offline analysis

$$N(i)_{corr} = \frac{N(i)}{DNL(i)+1}$$

PulXar Cu Ka spectrum (single pixel)

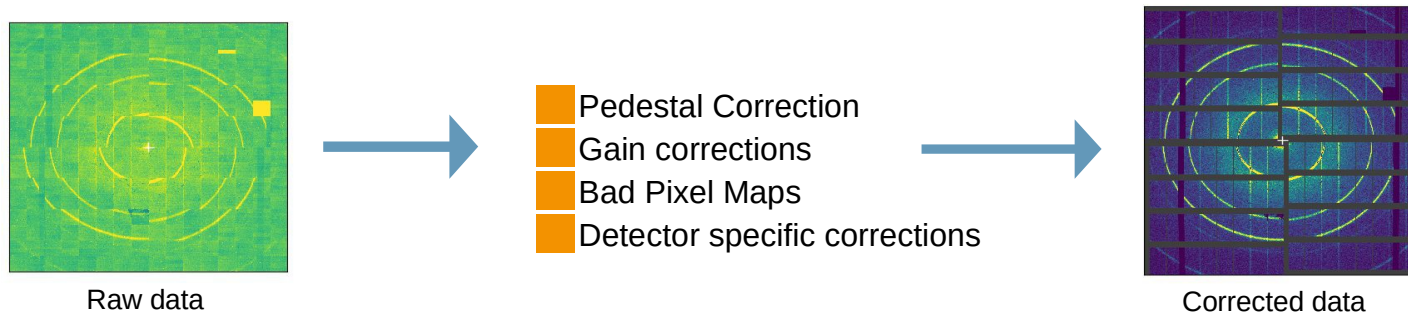


Calibration and raw data correction

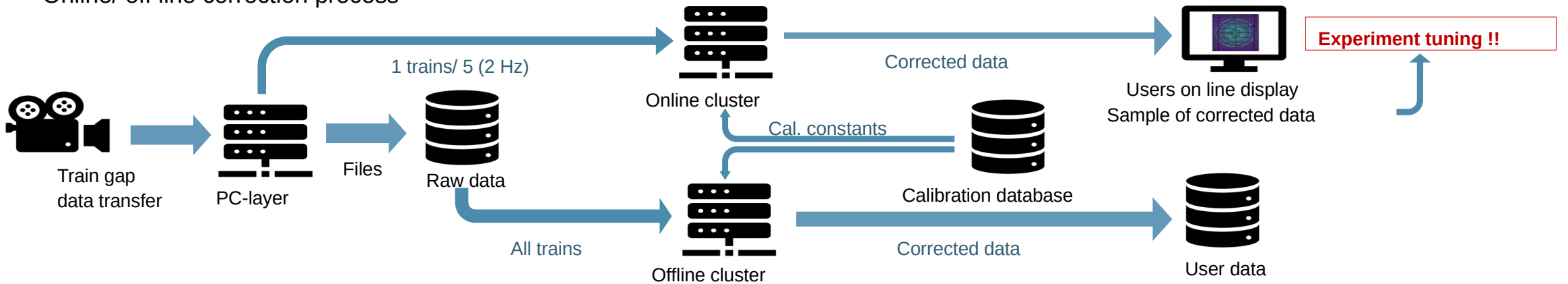
Calibration effort at European XFEL

European XFEL aims to provide facility users with a fully corrected and calibrated dataset as the primary data product.

SRN 27.4, 35 (2014)



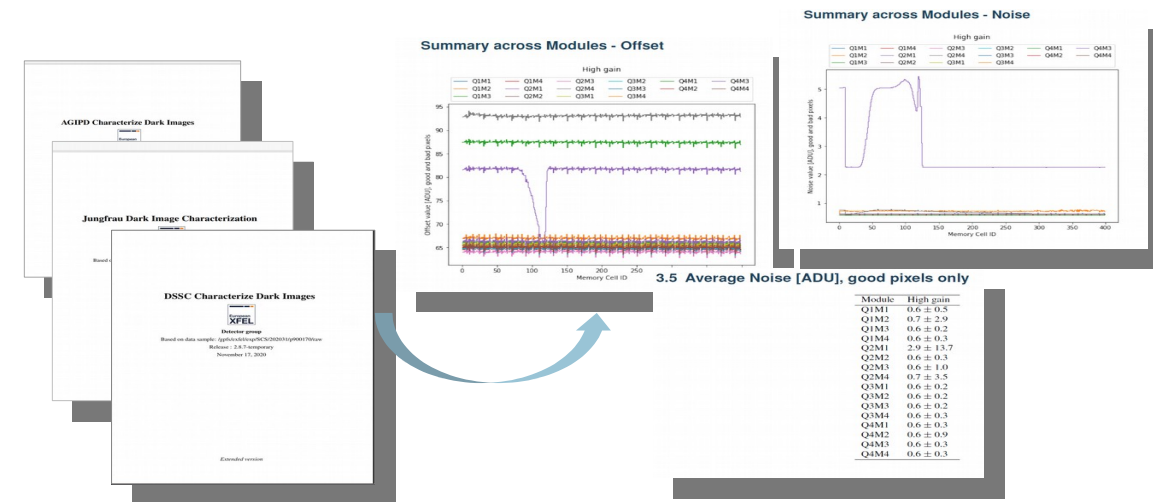
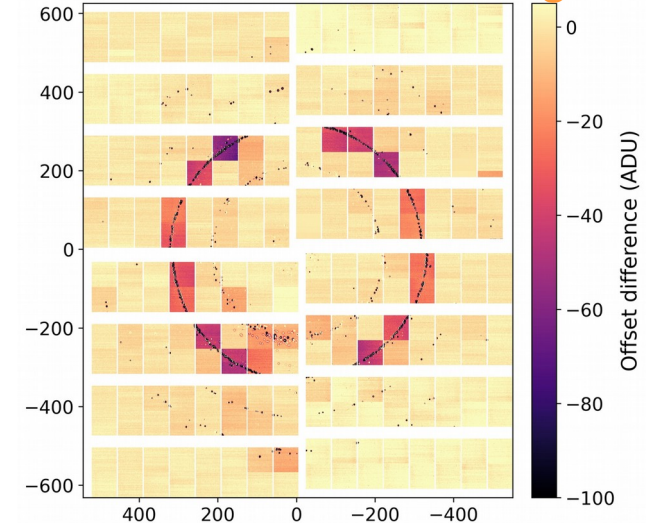
Online/ off line correction process



Keeping the calibration constants updated

- EuXFEL must provide the tools to achieve best data quality
 - Provide high quality corrected data
 - provide a reliable online preview
- We need to **update the correction constants regularly**
- **Quick to gather data: dark run constants**
 - Frequently updated (at least once per shift)
 - Pedestal and noise
 - Bad pixel classification (from pedestal and noise values)
 - ▶ Automated procedure for acquisition and calculation
 - ▶ No need to expert supervision
- **Special calibration procedures**
 - Need expert contribution to acquire and process
 - ▶ Gain constants
 - ▶ NLR curves
 - ▶ DNL
 - ▶ ...
 - Automation of procedures still on the way
 - Updated when possible (e.g. during shutdowns)

AGIPD radiation damage



Handling raw data: correction pipeline

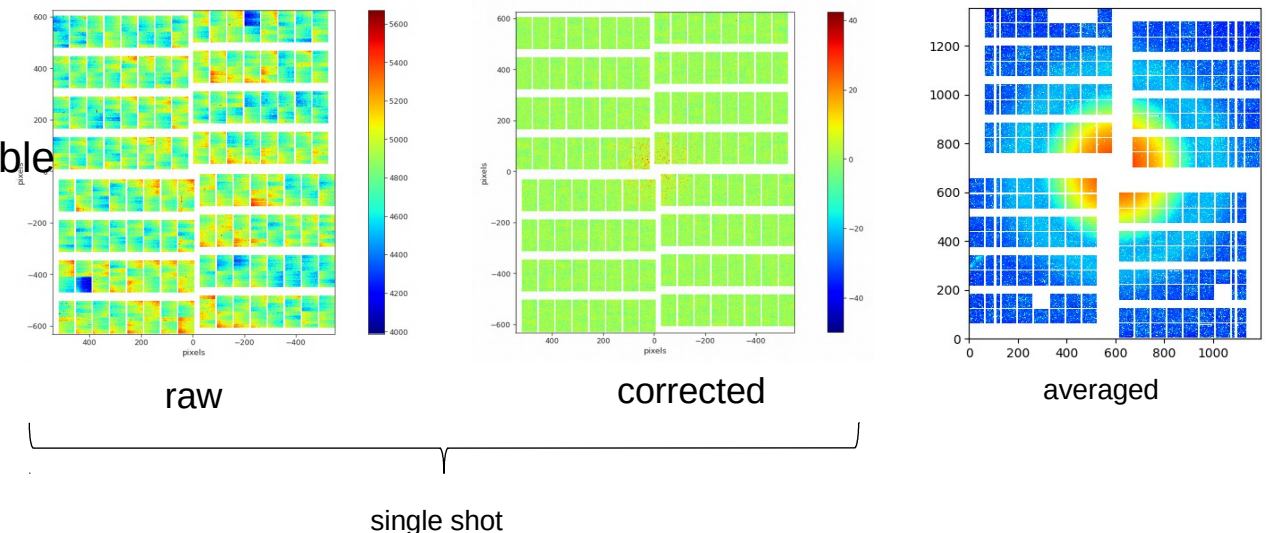
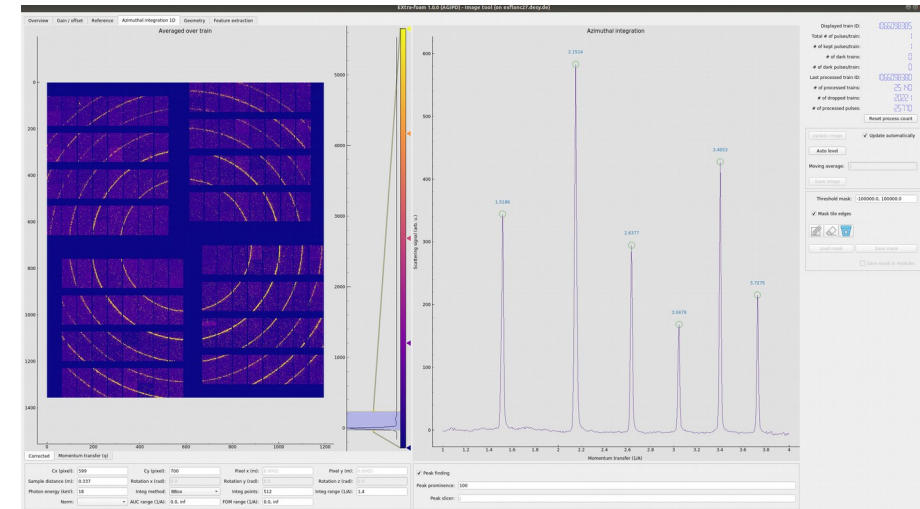
Constants loaded in DB

Online correction


- Implemented in EuXFEL control software (Karabo)
 - Detector class specific
 - Basic correction only
 - Code optimized for speed
 - Run on high performance machines
- Accessible from GUI
- Output corrected image
 - **Necessary for experiment tuning!**

Offline correction

- Implemented in scripts
 - Detector class specific
 - Algorithm aims to most complete correction possible
 - ▶ Common mode correction
 - ▶ Clustering
 - ▶ Baseline shift compensation ...
 - Code written to handle large data volumes
- Correction triggered by Metadata Catalogue
 - Scripts run a SLURM jobs on Maxwell Cluster



Summary

- European XFEL is an X-ray user facility with challenging requirements for detector development
 - **MHz-level pulse rate** in bursts
 - Up to 10^{14} photons per pulse
 - ▶ **High dynamic range required!**
 - ▶ High doses delivered to the detector
 - How we deal with high dynamic range
 - **Dynamic gain switching (AGIPD)**
 - ▶ Proven effective
 - ▶ Calibration issues
 - **Non-linear response (DEPFET DSSC)**
 - ▶ Calibration procedure successfully established
 - ▶ First user experiments will come soon
 - How to deal with MHz-level frame rates
 - **Analog storage cells (AGIPD)**
 - ▶ Cumbersome calibration
 - **On-chip analog to digital conversion (DSSC)**
 - ▶ Get rid of all analog storage cells effects
 - ▶ Limited resolution (8 bits)
- 
- Calibration constants updated when needed
 - **Effort to automatize calibration**
 - Provide the infrastructure to correct raw data
 - **Database to store the constants**
 - ▶ Offline correction pipeline
 - ▶ Online correction pipeline

Backup

Detectors for EuXFEL

Hard X-rays
6-25 keV

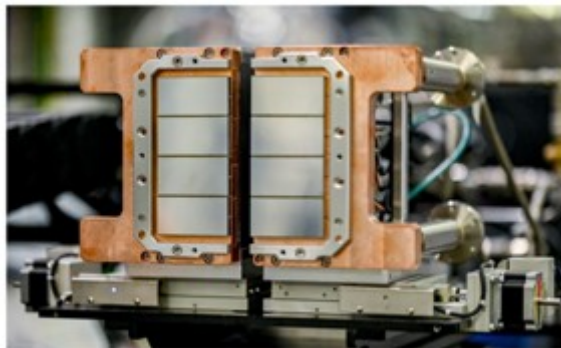
X-ray energy

Soft X-rays
0.5-3 keV



Noise: 50 e- (HG)
Dyn range: 100 8 keV ph

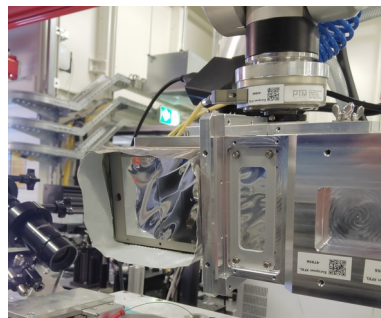
ePix100 (MID, HED)



JUNGFRAU x 18lrth (all hard X-ray inst.)

Noise: 80 e- (HG)
Dyn range: 10⁴ 12 keV ph

GOTTHARD-II (all instr.)



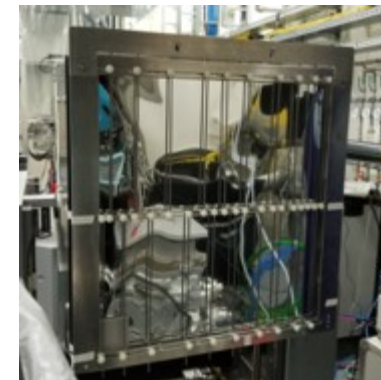
Strip detector
Noise: 280 e- (HG)
Dyn range: 10⁴ 12 keV ph
Up to 2700 images/train

AGIPD (SPB/SFX, MID)



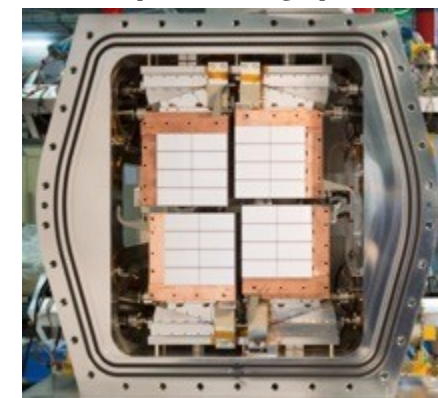
Noise: 350 e- (HG)
Dyn range: 10⁴ 12 keV ph

LPD (FXE)

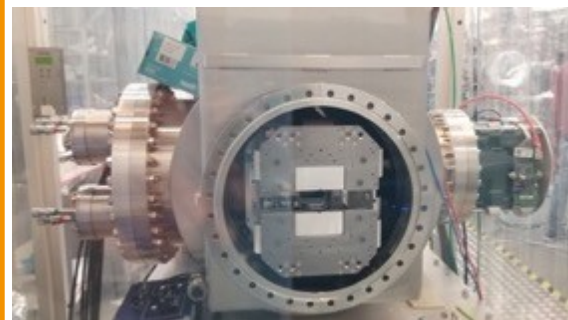


Noise: 2010 e- (HG)
Dyn range: 10⁵ 12 keV ph

DSSC (SCS, SQS)



Noise: 60 e-
Dyn range:
N x 256 ph @ 4.5 MHz -
N x 512 @ f≤2.2 MHz
N ≤ 1 for single ph sens.



pnCCD (SQS)

Noise: 3 e-
Dyn range: 1500-3000 1 keV ph

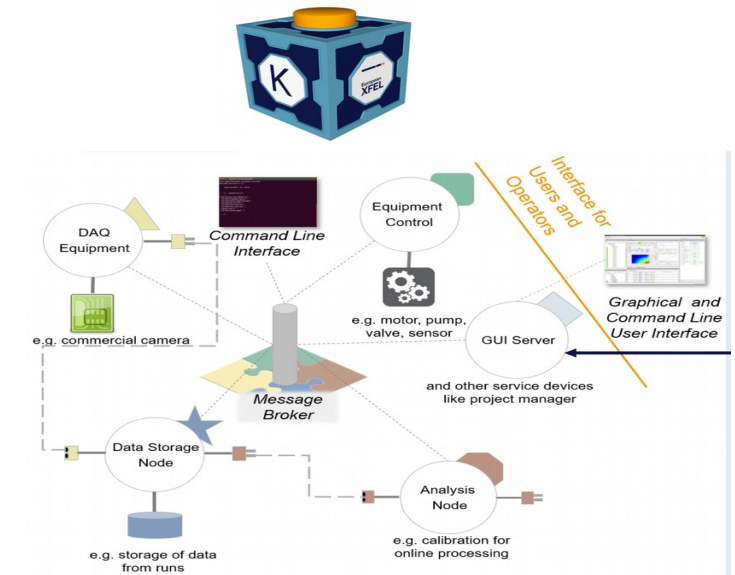
10 Hz

4.5 MHz

Rate

Detector integration in Karabo

- Karabo - European XFEL's Control System framework for control, DAQ and monitoring
 - Distributed system of devices (physical and 'logical') that communicate with each other through a message broker
 - Devices are aggregated in topics (one topic per instrument)
 - GUI Client facilitates interaction and control of devices
- Tight coupling of controls and DAQ
 - DAQ is generic for all data source (e.g. detector, motors, sensors, etc)
 - Data is stored centrally, ensuring easy accessibility
- Integration of detectors in Karabo
 - Enables control of the detector and its infrastructure
 - Supports complex procedures, including detector startup and calibration data collection
 - Provides monitoring capabilities (e.g., temperatures, power, detector status) and 2nd level detector protection
 - Data online viewers offer near real-time experiment feedback



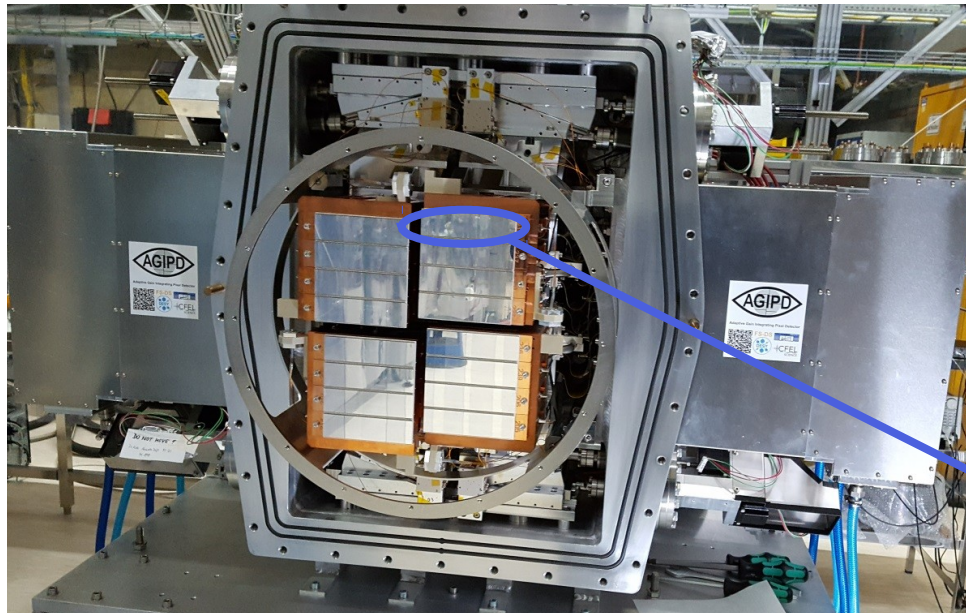
DAQ Run Controller

Source	type	behavior	mon
AGIPD1M_XTDF	✓		
MID_AGIPD1M_CTRL	✓		
MID_AGIPD1M_POWER_HV	✓		
MID_AGIPD1M_TEMP	✓		
MID_AGIPD1M_TSYS	✓		
EPHX3			
EPHX4			
JFS00K_CTRL_1			
JFS00K_CTRL_2			
JFS00K_M1			
JFS00K_M2			
MID_AGIPD1M_LITFRM			
MID_AJKT2_HG01			
MID_AJKT3_PAM			
MID_AJKT3_PAM_CAM1			
MID_AJKT3_PAM_CAM2			
MID_BSM			
MID_DET_S_GOTTHARD			
MID_DET_SINDC			
MID_DODCC_REQUESTOR			
MID_EXP_M00			
MID_EXP_DET3_CAM1			
MID_EXP_DET3_CAM2			
MID_EXP_DET3_CAM3			

Group	Alias	Data aggregator
6 MID_DET_AGI_	AGIPD11	MID_DET_AGIPD1M-1/DET11CH0
7 MID_DET_AGI_	AGIPD12	MID_DET_AGIPD1M-1/DET12CH0
8 MID_DET_AGI_	AGIPD13	MID_DET_AGIPD1M-1/DET13CH0
9 MID_DET_AGI_	AGIPD14	MID_DET_AGIPD1M-1/DET14CH0
10 MID_DET_AGI_	AGIPD15	MID_DET_AGIPD1M-1/DET15CH0
11 MID_DET_AGI_	AGIPD01	MID_DET_AGIPD1M-1/DET1SCH0
12 MID_DET_AGI_	AGIPD02	MID_DET_AGIPD1M-1/DET2SCH0
13 MID_DET_AGI_	AGIPD03	MID_DET_AGIPD1M-1/DET3SCH0
14 MID_DET_AGI_	AGIPD04	MID_DET_AGIPD1M-1/DET4SCH0
15 MID_DET_AGI_	AGIPD05	MID_DET_AGIPD1M-1/DET5SCH0
16 MID_DET_AGI_	AGIPD06	MID_DET_AGIPD1M-1/DET6SCH0
17 MID_DET_AGI_	AGIPD07	MID_DET_AGIPD1M-1/DET7SCH0
18 MID_DET_AGI_	AGIPD08	MID_DET_AGIPD1M-1/DET8SCH0
19 MID_DET_AGI_	AGIPD09	MID_DET_AGIPD1M-1/DET9SCH0

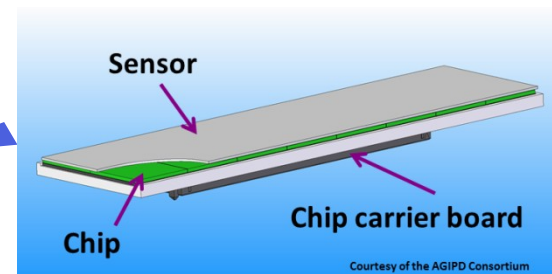
Device (Alias)	Status	Score	Load
0 RunController	MONITORING		
1 AGIPD00	MONITORING	1(21)	
2 AGIPD01	MONITORING	1(21)	
3 AGIPD02	MONITORING	1(21)	
4 AGIPD03	MONITORING	1(21)	
5 AGIPD04	MONITORING	1(21)	
6 AGIPD05	MONITORING	1(21)	
7 AGIPD06	MONITORING	1(21)	
8 AGIPD07	MONITORING	1(21)	
9 AGIPD08	MONITORING	1(21)	
10 AGIPD09	MONITORING	1(21)	
11 AGIPD10	MONITORING	1(21)	
12 AGIPD11	MONITORING	1(21)	
13 AGIPD12	MONITORING	1(21)	
14 AGIPD13	MONITORING	1(21)	
15 AGIPD14	MONITORING	1(21)	
16 AGIPD15	MONITORING	1(21)	
17 AGIPD1MCTRL00	MONITORING	4(1415)	
18 AGIPD1MCTRL01	MONITORING	1(11505)	
19 ADIHC001	PASSIVE		
20 DA00	PASSIVE		
21 DA01	PASSIVE		
22 DA02	PASSIVE		
23 DA03	PASSIVE		
24 DA04	PASSIVE		
25 DA05	PASSIVE		
26 DA06	PASSIVE		
27 DA07	PASSIVE		
28 DA08	PASSIVE		
29 DA09	PASSIVE		
30 DA010	PASSIVE		

AGIPD1M detector system for SPB/SFX and MID instruments



Hybrid detector module

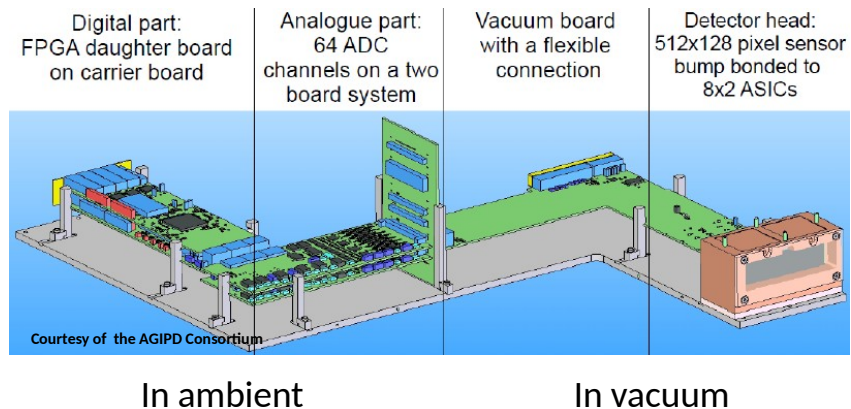
- Sensor:
 - 128 x 512 pixels
 - 500 μm thick silicon
- 2 x 8 read-out chips connected to sensor via bump-bonding
- Size: $\sim 26 \times 105 \text{ mm}^2$



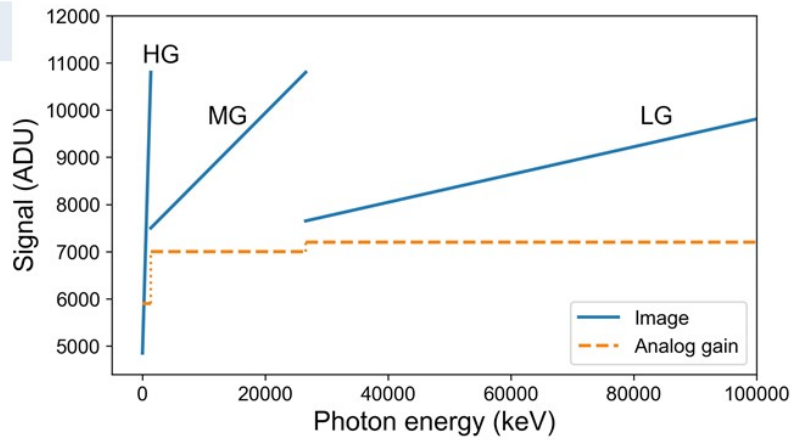
1M AGIPD system

- 16 modules are mounted on four independently movable quadrants
- Vacuum operation ($P < 10^{-5}$ mbar)
- Electronics/Control: two independent detectors: 'half 1' and 'half 2'
- Readout: 16 independent detectors

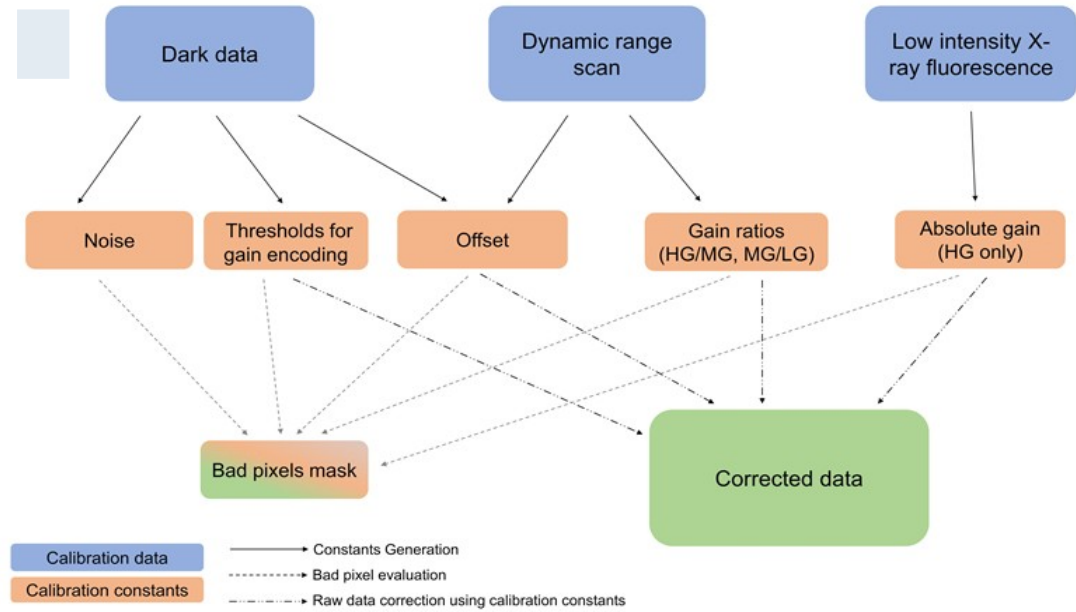
■ European XFEL



Dynamic gain switching calibration



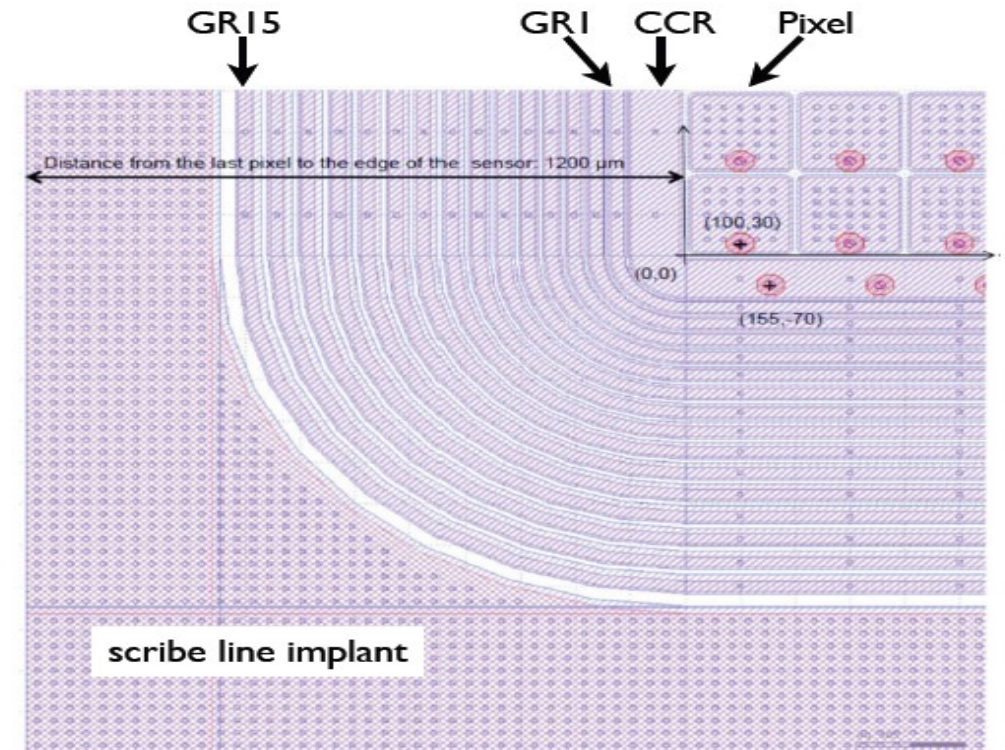
AGIPD Calibration for one operation mode



Data Type	Data Size	Measurement Time	Data Processing Time	Frequency
Dark Data	2.2 TB	5 mins	~ 10 mins	at least once per shift
Dynamic Range Scan - Pulsed Capacitor	8.2 TB	20 mins	~ 100 mins	6 months
Dynamic Range Scan - Current Source	21 TB	65 mins	~ 180 mins	6 months
Fluorescence Data	15-20 TB	25-30 mins	up to 720 mins	6-12 months

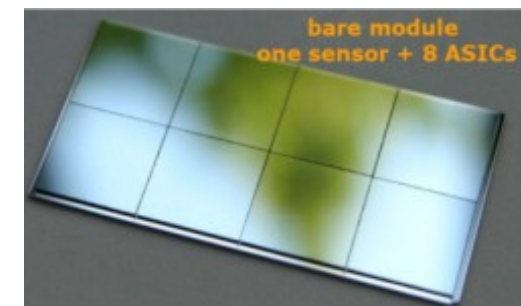
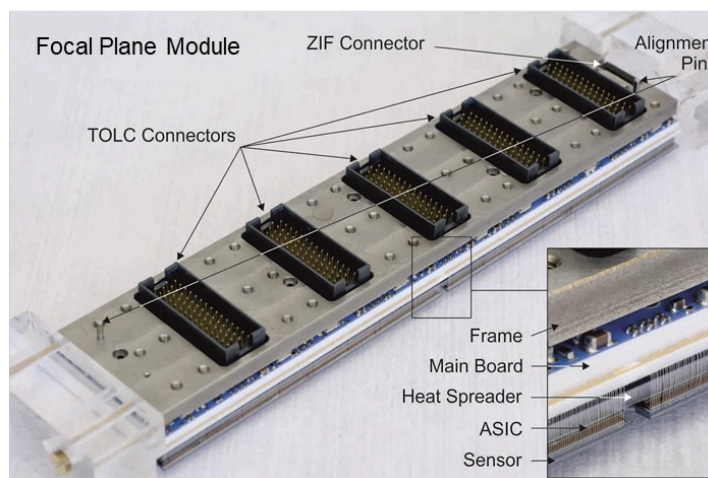
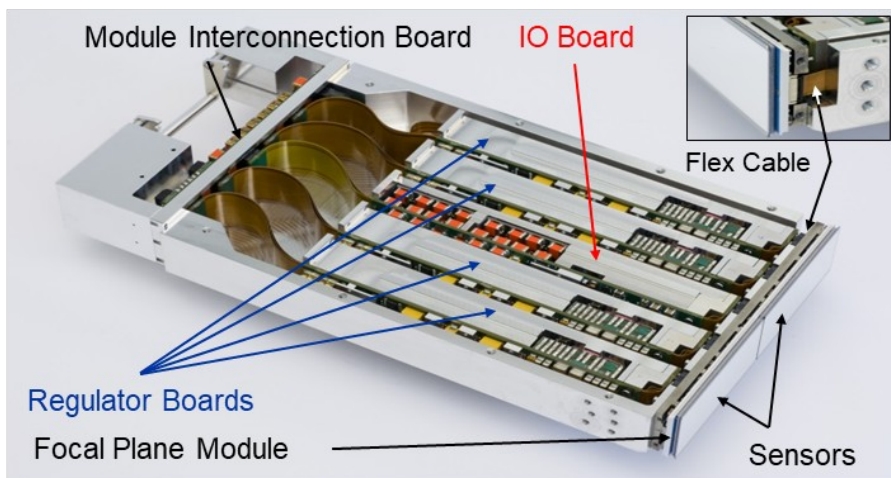
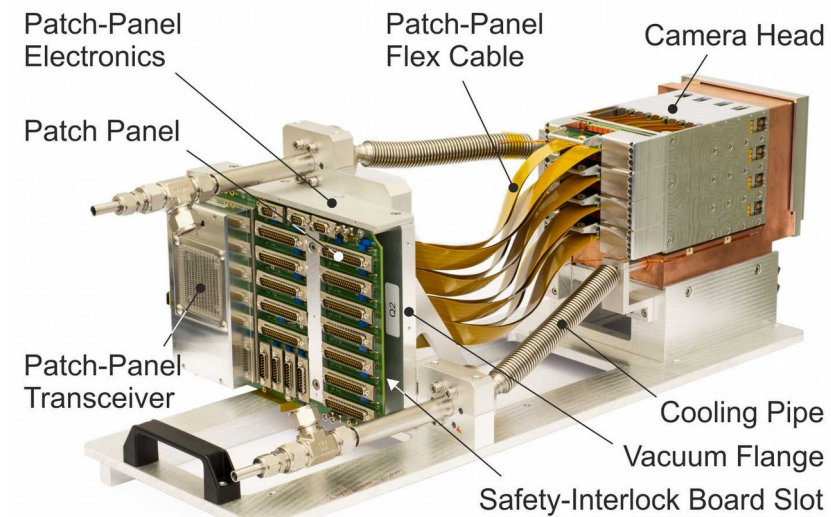
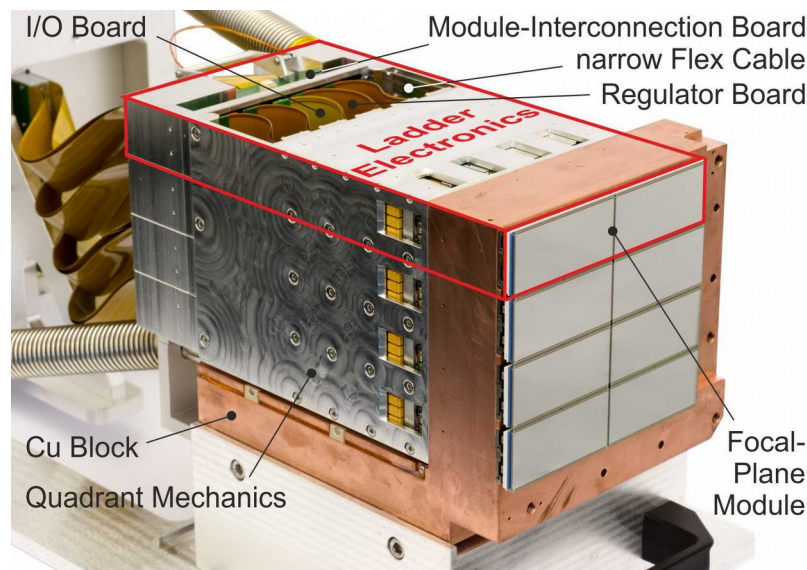
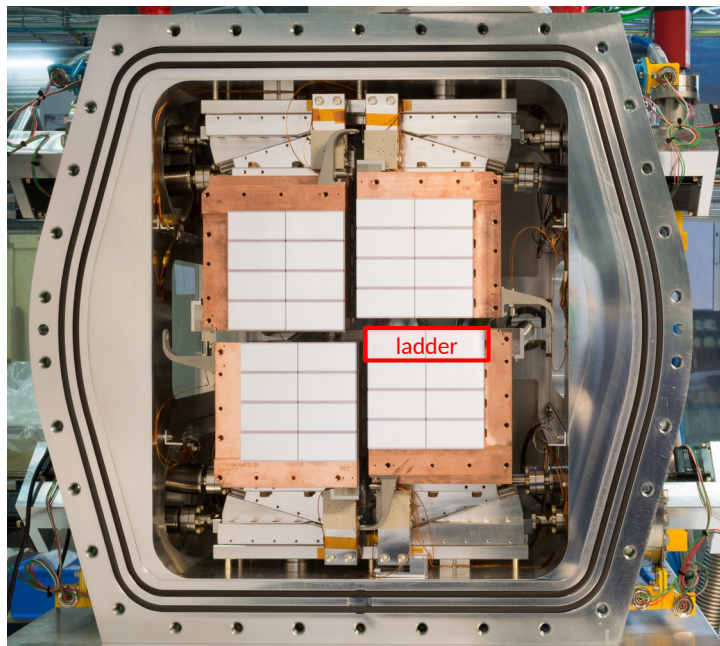
Radiation hardness sensor design

- No bulk damage expected for $E < 300 \text{ keV}$
BUT
 - Surface and interface damage:
 - Higher leakage current
 - Higher depletion voltage
 - Lower breakdown voltage
 - Charge losses at interface
 - Increased inter-pixel capacitance
- ➔ Special high voltage design with 15 guard rings:
- radiation tolerant up to 1GGy \equiv
 - introduced additional non-sensitive area between detector modules \equiv



Distance from the last pixel to the edge of the sensor 1200 μm

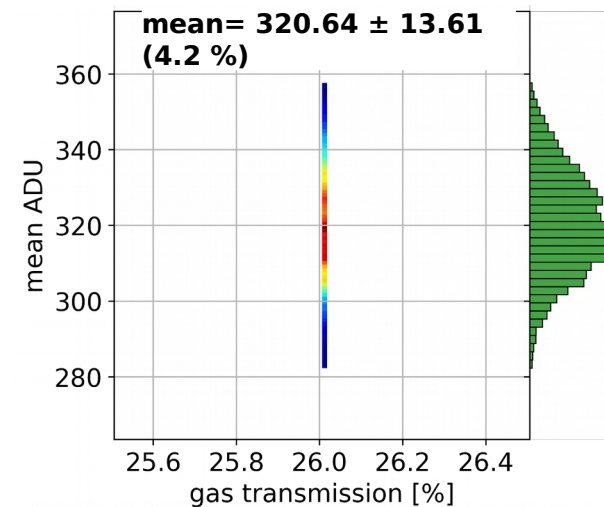
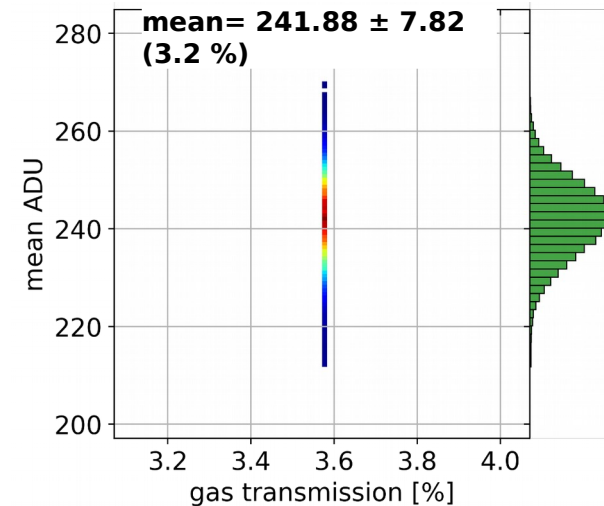
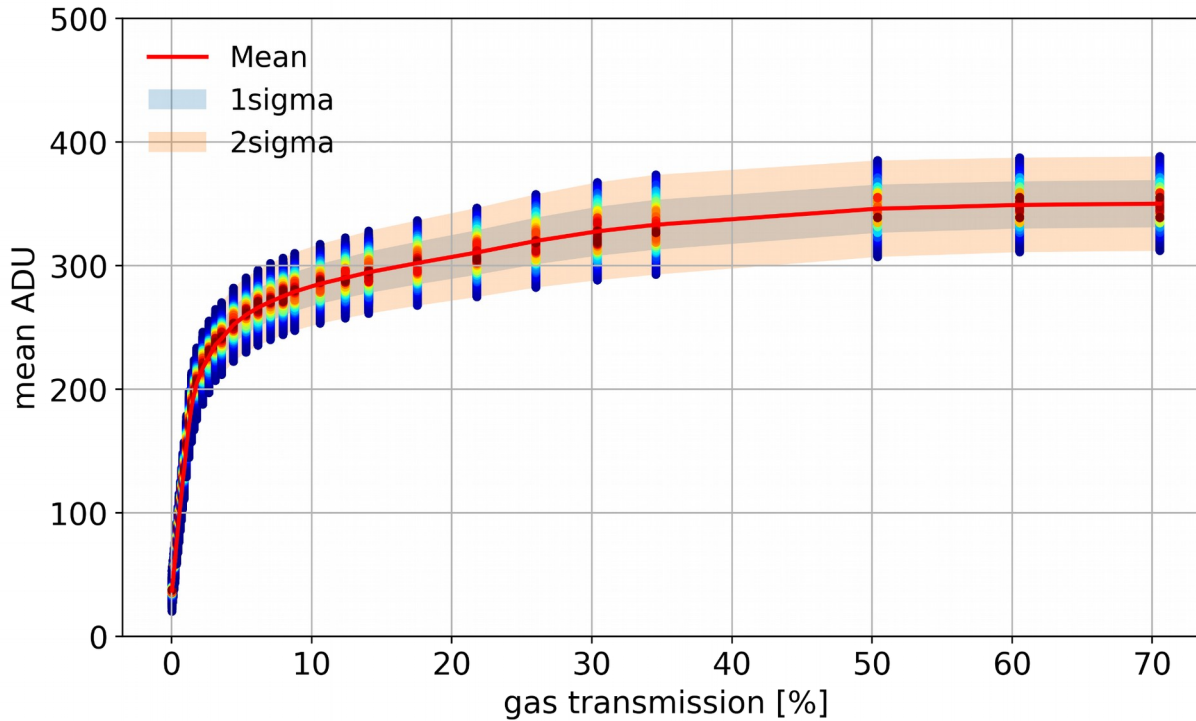
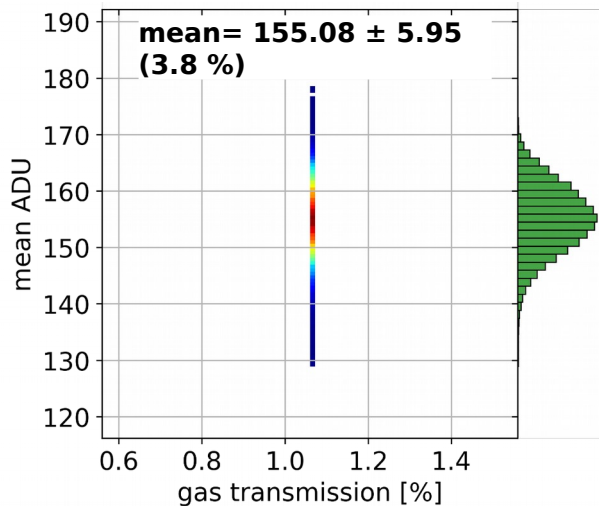
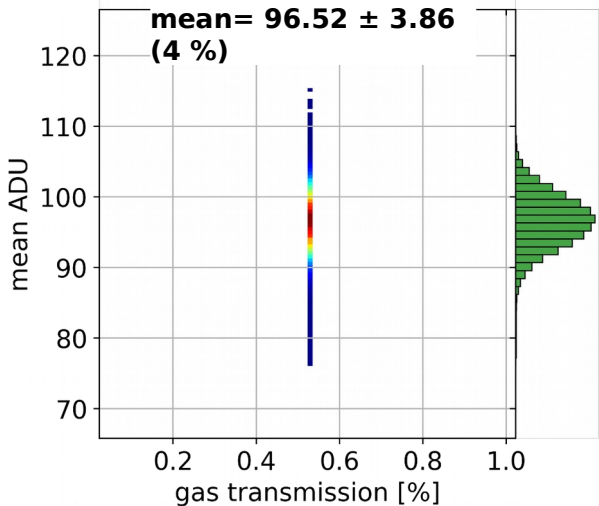
JINST (2013) 8 C12015,
DOI: 10.1088/1748-0221/8/01/C01015,
e-Print: arXiv:1210.0430 [physics.ins-det]



- Movable quadrants
- “service position” in the pic
- Total active area ~ 505 cm²
- Minimum insensitive area ~15%

NLR curves of DEPFET pixels

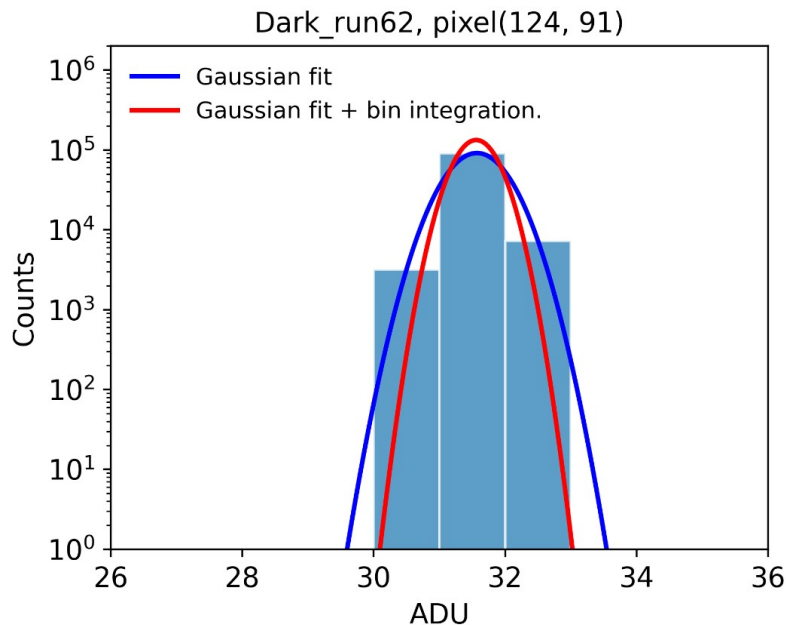
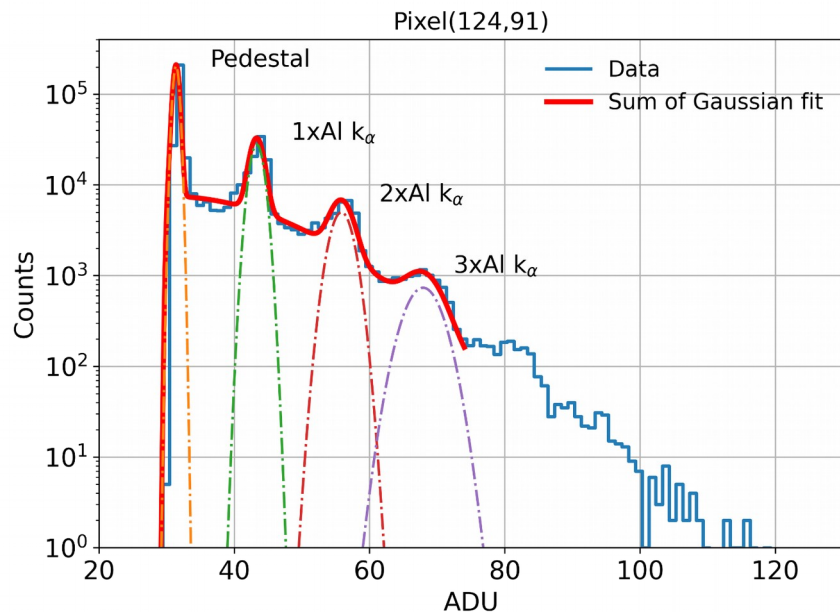
gain: C_{fcf}=3, T_{int}=50 ns, Freq=2.2 MHz, T=18 °C



European XFEL

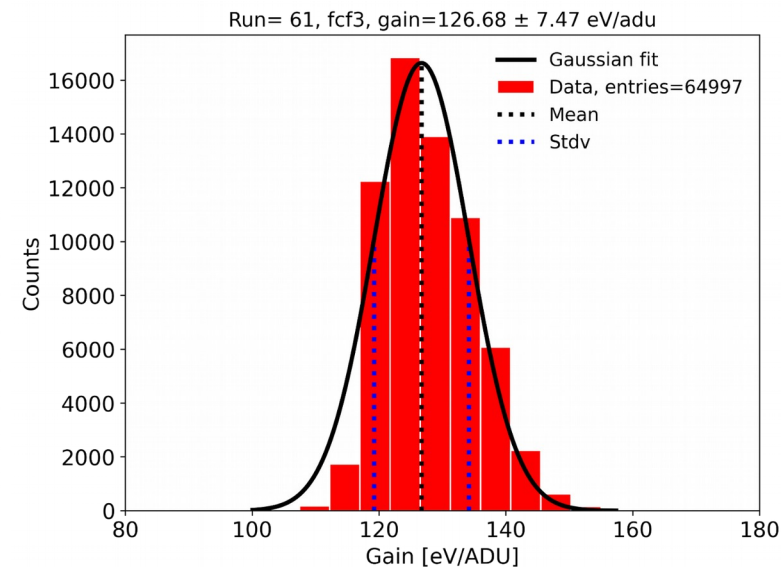
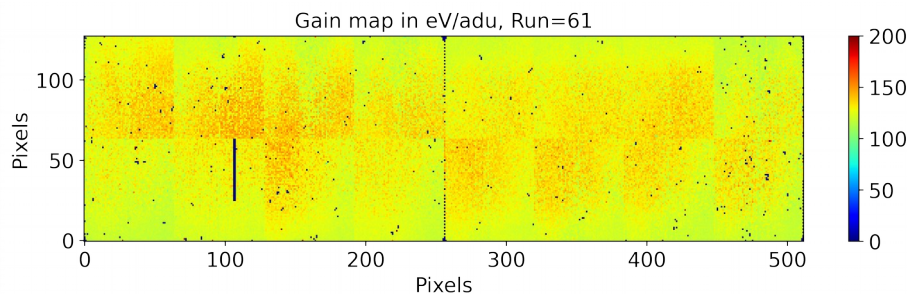
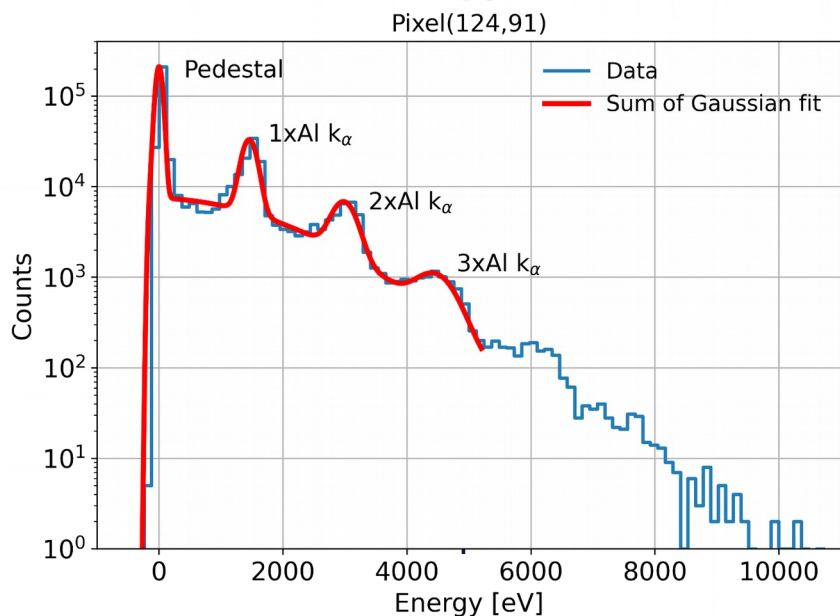
Spectroscopic performance of DEPFET: Single photon detection

F = 1.1 MHz, $T_{int} = 100$ ns, T = 18 °C

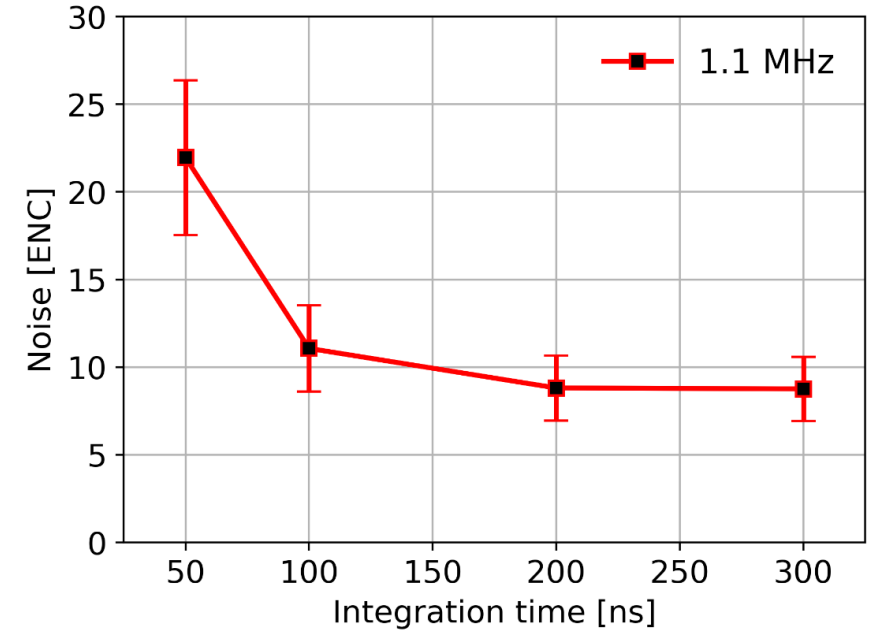
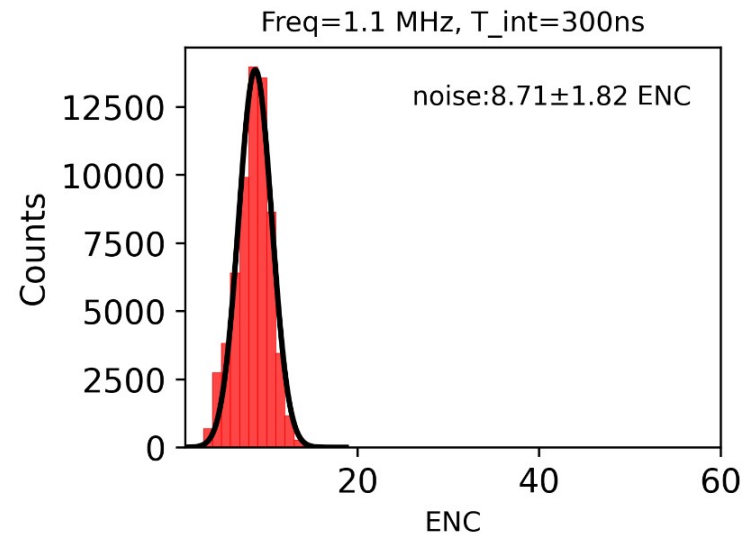
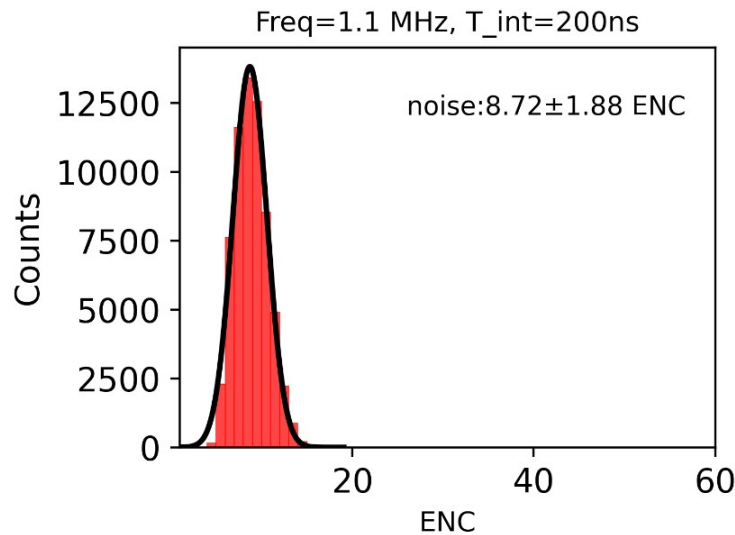
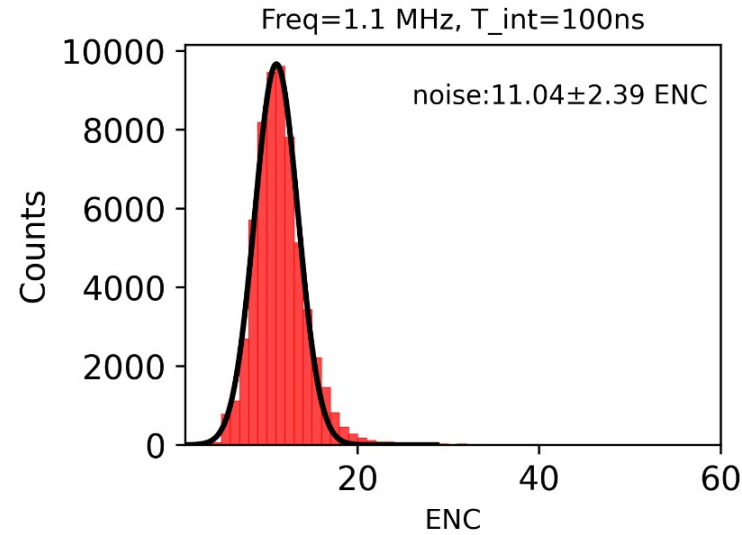
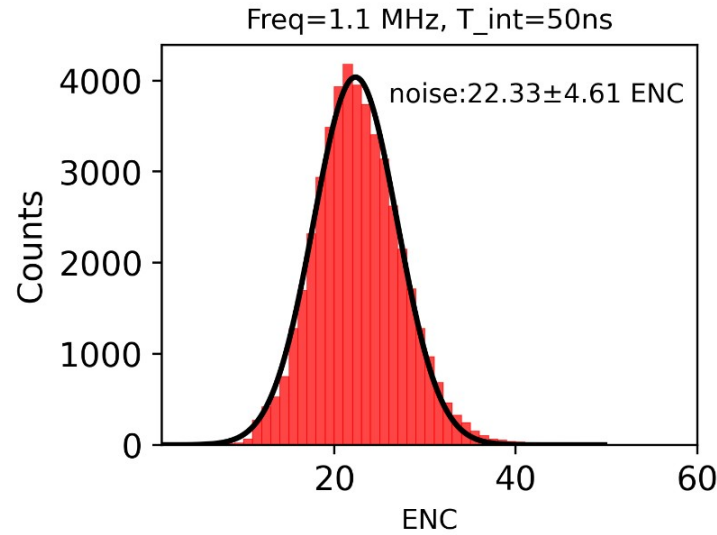


- F = 1.1 MHz, $T_{int} = 100$ ns
- Gaussian: 31.57 ± 0.41
- Gaussian + bin intg.: 31.56 ± 0.3
- Pixel gain: 122 eV/adu
- Pixel noise: 10.1 ENC
- Pixel(124, 91) SNR = 40

SNR = Energy of Al k_α photon/ noise



Noise performance of DEPFET pixels

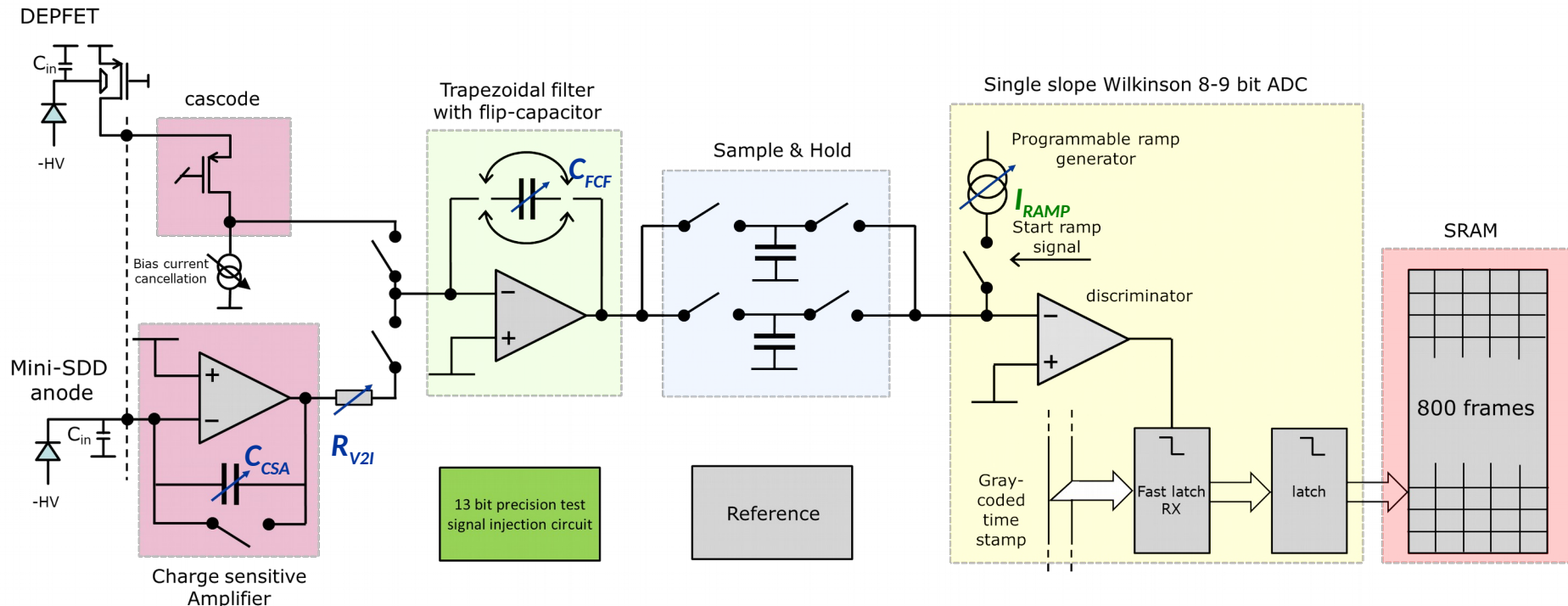
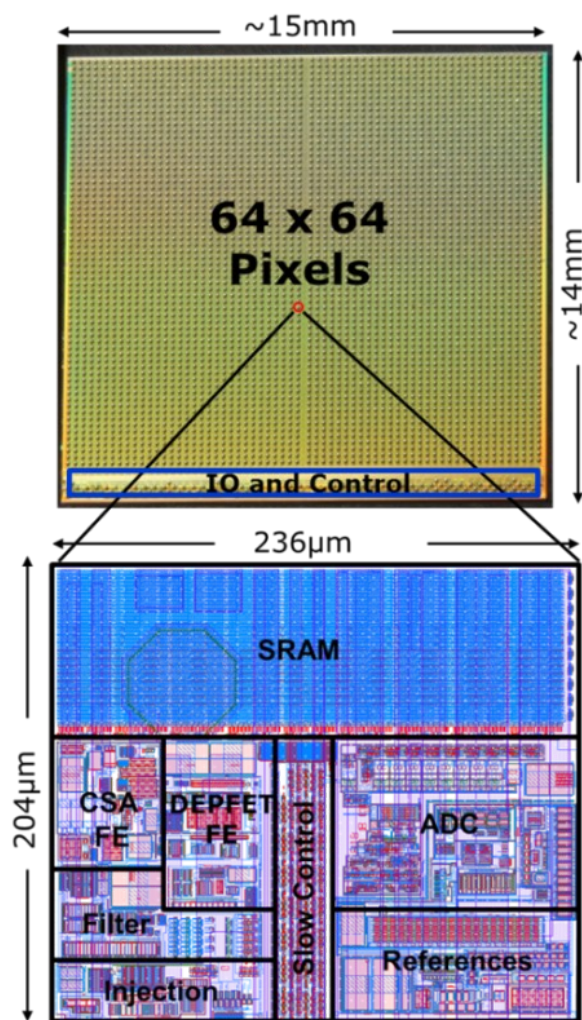


Flip Capacitor Filter technique



Noise reduction with increasing integration time

No MHz X-ray Camera can operate with such very low noise (i.e. 8 ENC)



- Gain and offset can be adjusted pixel-wise:
 - **11 bits of coarse gain setting** for ph. energy and input range selection
 - **6 bits of gain fine trimming** (nominal accuracy 2%)
 - 4 bits for offset trimming (1.5 LSB range with 8% of granularity)

130 nm CMOS Process with C4 bumps

$$\frac{\text{keV}}{\text{ADU}} \propto \underbrace{C_{CSA} \cdot R_{V2I} \cdot C_{FCF}}_{\text{Pixel-wise coarse gain parameters}} \cdot \frac{1}{t_{filt}} \cdot \frac{1}{C_{S\&H}} \cdot \underbrace{I_{ramp}}_{\text{Pixel-wise fine gain trimming}} \cdot \frac{1}{2 \cdot f_{clock}}$$